

TransistorTester with AVR microcontroller
and a little more
Version 1.04k

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Preface

Basically Motive

Every hobbyist knows the following problem: You disassemble a Transistor out of a printed board or you get one out of a collection box. If you find out the identification number and you already have a data sheet or you can get the documents about this part, everything is well. But if you don't find any documents, you have no idea, what kind of part this can be. With conventional approach of measurement it is difficult and time-consuming to find out the type of the part and parameters. It could be a NPN, PNP, N- or P-Channel-Mosfet etc. It was the idea of Markus F. to hand over the work to a AVR microcontroller.

As my work has started





My work with the software of the TransistorTester of Markus F. [1] has started, because I had problems with my programmer. I had bought a printed board and components, but I could not program the EEprom of the ATmega8 with the Windows driver without error messages. Therefore I took the software of Markus F. and changed all the accesses from the EEprom memory to flash memory accesses. By analysing the software in order to save memory at other places of program, I had the idea, to change the result of the ReadADC function from ADC units to millivolt (mV) units. The mV resolution is needed for any output of voltage values. If ReadADC returns directly the mV resolution, I can save the conversion for each output value. This mV resolution can be get, if you first accumulate the results of 22 ADC readings. The sum must be multiplied with two and divided by nine. Then we have a maximum value of $\frac{1023 \cdot 22 \cdot 2}{9} = 5001$, which matches perfect to the wanted mV resolution of measured voltage values. So I additionally had the hope, that the enhancement of ADC resolution by oversampling could help to improve the voltage reading of the ADC, as described in AVR121 [5]. The original version ReadADC has accumulated the result of 20 ADC measurements and divides afterwards by 20, so the result is equal to original ADC resolution. By this way never a enhancement of ADC resolution can take place. So I had to do little work to change the ReadADC, but this forced analysing the whole program and change of all "if-statements" in the program, where voltage values are queried. But this was only the beginning of my work!

More and more ideas to make measurement faster and more accurate has been implemented. Additionally the range of resistor and capacity measurements are extended. The output format for LCD-Display was changed, so symbols are taken for diodes, resistors and capacitors instead of text. For further details take a look to the actual feature list chapter 1. Planned work and new ideas are accumulated in the To Do List in chapter 8. By the way, now I can program the EEprom of the ATmega with Linux operating system without errors.

At this place I would like to thank the originator and software author Markus Frejek, who has enabled the continuation with his initial work. In addition I would like to say thanks to the authors of numerous input to the discussion forum, which have assist me, to find new tasks, weak points and errors. Next I would like to thank Markus Reschke, who give me the permission, to publish his cheerful software versions at the SVN server. Furthermore some ideas and software part of Markus R. was integrated in my own software version, again thank you very much. I have to thank also Asco B., who has developed a new printed board, to enable the reproductions for other hobbyists. Another thank I would like to send to Dirk W. , who has handled the omnibus order for this printed board. Never I had time enough to handle these things concurrently with my software development, at no time the state of further development of software would have the same level.

Chapter 1

Features

1. Operates with ATmega8, ATmega168 or ATmega328 microcontrollers.
2. Displaying the results to a 2x16 character LCD-Display.
3. One key operation with automatic power shutdown.
4. Battery operation is possible since shutdown current is only about 20nA.
5. Low cost version is feasible without crystal and auto power off.
6. Automatic detection of NPN and PNP bipolar transistors, N- and P-Channel MOSFETs, JFETs, diodes, double diodes, Thyristors and Triacs.
7. Automatic detection of pin layout of the detected part.
8. Measuring of current amplification factor and Base-Emitter threshold voltage of bipolar transistors.
9. Darlington transistors can be identified by the threshold voltage and high current amplification factor.
10. Detection of the protection diode of bipolar transistors and MOSFETs.
11. Measuring of the Gate threshold voltage and Gate capacity value of MOSFETs.
12. Up to two Resistors are measured and shown with symbols  and values with up to four decimal digits in the right dimension. All symbols are surrounded by the probe numbers of the Tester (1-3). So Potentiometer can also be measured. If the Potentiometer is adjusted to one of its ends, the Tester cannot differ the middle pin and the end pin.
13. Resolution of resistor measurement is now 0.1Ω , values up to $50M\Omega$ are detected.
14. One capacitor can be detected and measured. It is shown with symbol  and value with up to four decimal digits in the right dimension. The value can be from 25pF (8MHz clock, 50pF @1MHz clock) to 100mF. The resolution can be up to 1 pF (@8MHz clock].
15. For capacitors with a capacity value above $2\mu F$ the Equivalent Serial Resistance (ESR) is measured with a resolution of 0.01Ω and shown with two significant decimal digits. This feature is only available for ATmega with at least 16K flash memory (ATmega168 or ATmega328).
16. Up to two diodes are shown with symbol  or symbol  in correct order. Additionally the flux voltages are shown.

17. LED is detected as diode, the flux voltage is much higher than normal. Two-in-one LEDs are also detected as two diodes.
18. Zener-Diodes can be detected, if reverse break down Voltage is below 4.5V. These are shown as two diodes, you can identify this part only by the voltages. The outer probe numbers, which surround the diode symbols, are identical in this case. You can identify the real Anode of the diode only by the one with break down (threshold) Voltage nearby 700mV!
19. If more than 3 diode type parts are detected, the number of founded diodes is shown additionally to the fail message. This can only happen, if Diodes are attached to all three probes and at least one is a Z-Diode. In this case you should only connect two probes and start measurement again, one after the other.
20. Measurement of the capacity value of a single diode in reverse direction. Bipolar Transistors can also be analysed, if you connect the Base and only one of Collector or Emitter.
21. Only one measurement is needed to find out the connections of a bridge rectifier.
22. Capacitors with value below 25pF are usually not detectet, but can be measured together with a parallel diode or a parallel capacitor with at least 25pF. In this case you must subtract the capacity value of the parallel connected part.
23. For resistors below 2100Ω also the measurement of inductance will be done, if your ATmega has at least 16K flash memory. The range will be from about $0.01mH$ to more than $20H$, but the accuracy is not good. The measurement result is only shown with a single component connected.
24. Testing time is about two seconds, only capacity or inductance measurement can cause longer period.
25. Software can be configured to enable series of measurements before power will be shut down.
26. Build in selftest function with optional 50Hz Frequency generator to check the accuracy of clock frequency and wait calls (ATmega168 and ATmega328 only).
27. Selectable facility to calibrate the internal port resistance of port output and the zero offset of capacity measurement with the selftest (ATmega168 and ATmega328 only). A external capacitor with a value between $100nF$ and $20\mu F$ connected to pin 1 and pin 3 is necessary to compensate the offset voltage of the analog comparator. This can reduce measurement errors of capacitors of up to $40\mu F$. With the same capacitor a correction voltage to the internal reference voltage is found to adjust the gain for ADC measuring with the internal reference.

Thyristors and Triacs can only be detected, if the test current is above the holding current. Some Thyristors and Triacs need as higher gate trigger current, than this Tester can deliver. The available testing current is only about 6mA! Notice that all features can only be used with microcontroller with more program memory such as ATmega168.

Attention: Allways be shure to **discharge capacitors** before connecting them to the Tester! The Tester may be damaged before you have switched it on. There is only a little protection at the ATmega ports.

Extra causion is required if you try to test components mounted in a circuit. In either case the equipment should be disconnected from power source and you should be shure, that **no residual voltage** remains in the equipment.

Chapter 2

Hardware

2.1 Circuit of the TransistorTester

The circuit of the TransistorTester in figure 2.1 is based on the circuit of Markus F. released in Abb. 1 of AVR-Transistortester report [1]. Changed or moved parts are marked with green color, optional parts are marked with red color.

Some changes are made because the electronical power switch make problems in some implementations. Therefore the resistor R7 is reduced to $3.3k\Omega$. The capacitor C2 is reduced to 10nF and R8 is moved so that the PD6 output does not try to switch the C2 capacitor directly. Additional blocking capacitors are added and should be placed near the power connection of the Atmega and near the Voltage regulator.

Because the PD7 input and PC6 (RESET) are the only pins, where pull up resistors where needed, one extra $27k\Omega$ resistor is added to the PD7 (pin 13) input. With this modification the software can disable all internal pull up resistors of the ATmega.

The additional crystal with its 22pF capacitors are optional added. The accuracy of a crystal has the benefit of more stable time measurement for getting the capacitor values.

New software version can use a voltage scale switch of the ADC. The speed of switching is reduced by the external capacitor C1 at the AREF (21) pin of the ATmega. To avoid slowing down the measurement speed more than necessary, the value of this capacitor should be reduced to 1nF. Removing of the capacitor C1 is also possible. For adapting the software to the actual circuit take a look to the Makefile options in the configuring chapter 4.

Some different versions of R11 / R12 resistor combinations circulates in the internet. I have adapted my software to the original of Markus F. [1] with $10k\Omega$ and $3.3k\Omega$.

The additional 2.5V precision voltage reference connected at pin PC4 (ADC4) can be used to check and calibrate the VCC voltage, but is not required. A optional ISP connector has been added to easier load new software versions to the tester.

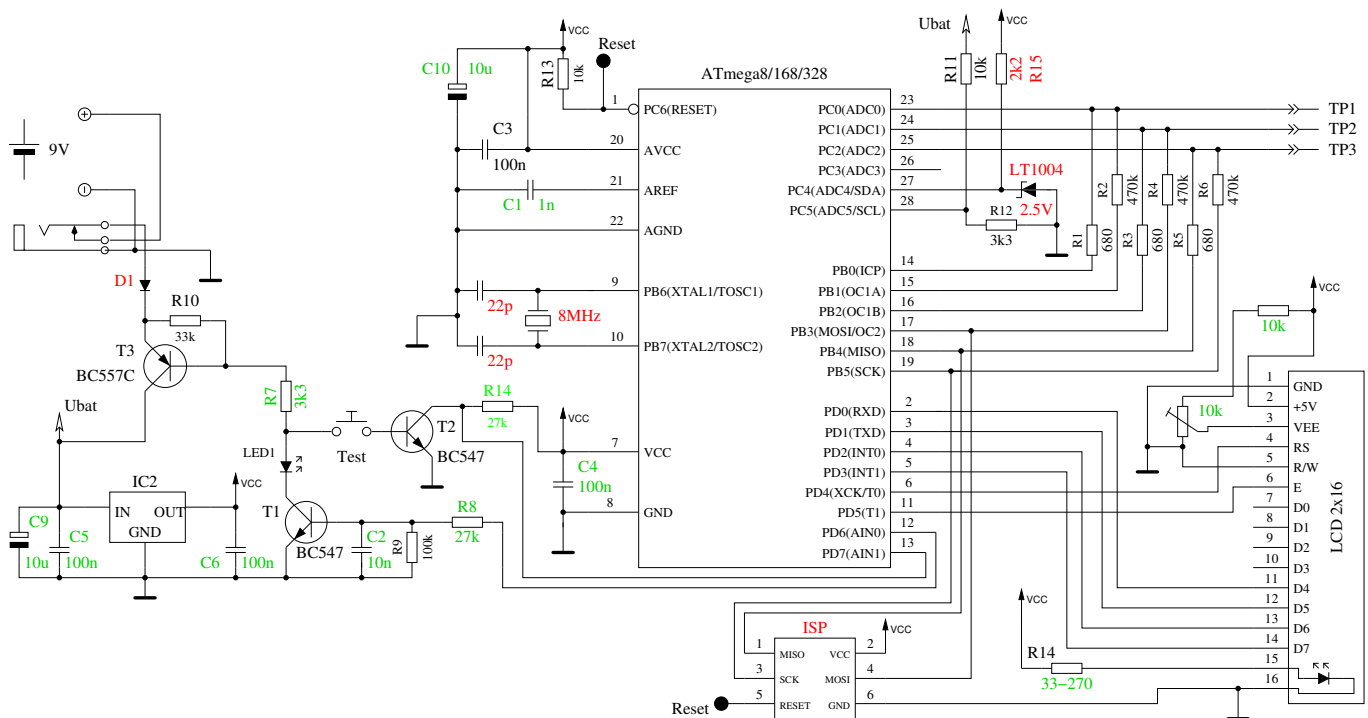


Figure 2.1: New circuit of TransistorTester

The software can follow to another pin assignment of port D for a simpler connection of the LCD display. The following table 2.1 shows the modified assignments.

Signal	circuit diagram	strip grid board version
pushbutton input	PD7	PD0
LCD-RS	PD4	PD7
LCD-E	PD5	PD5
LCD-D4	PD0	PD4
LCD-D5	PD1	PD3
LCD-D6	PD2	PD2
LCD-D7	PD3	PD1

Table 2.1: Changes for strip grid board

2.2 Hints for building the TransistorTester

Every LCD-display with at least 2x16 character and a HD44780 compatible controller can be used with the TransistorTester. You should respect the current needed for illumination, some LCD need lower current than others. I had tried OLED type displays, but this type cause interference with measurements of the ATmega and are **not** recommended. Also loading of special characters for displaying the resistor symbol has caused problems with the OLED.

The resistors R1 to R6 are critical for measurements and this 680Ω and 470kΩ resistors should be measurement type resistors (tolerance of 0.1%) to get the full accuracy. You should use a precision socket for the ATmega microcontroller to enable the replacement of the microcontroller. The microcontroller ATmega8, ATmega168 and ATmega328 can be used. Recommended is a ATmega168 or ATmega328, if you wish to use all features.

Anyway you should assemble all parts to printed board without the microcontroller. A up-to-date low voltage drop regulator like MCP1702-5002 is recommended as IC2, because it need only 2μA of

standby current and can still deliver 5V, if your input voltage is only 5.4V. But this part is not pin compatible to well known 78L05 with TO92 body!

After checking, that all needed parts are at the correct place, you should first connect the battery or power supply to the printed board without LCD-display and microcontroller. You should check the voltage at the power pins of the microcontroller and LCD-display terminal during the Test key is pressed. The voltage should disappear, if you release the Test key. If the voltage had correct polarity and value, you should disconnect the power and assemble the microcontroller with correct alignment. Be careful and make shure, that all pins of the microcontroller are in the socket holes. Now you can also connect the LCD. Check if power pins of the LCD has the right connection to GND and VCC of your board.

If you are shure that everything is all right, reconnect the power. If you have already programmed the ATmega, you can press the Test button. By pressing the Test key, the background light of the LCD should switch on. If you release the Test button, the LED should illuminate weak. Notice, that the software for the microcontroller must be compiled for the correct processor type. A program for the ATmega8 does not run on a ATmega168!

2.3 Programming of the microcontroller

I release the software for the microcontroller with source code. The developement is done with Linux operationg system (Ubuntu) and is controlled with a Makefile. The Makefile makes shure, that your software will be compiled with the prior selected Makefile options. Some constellations are precompiled with the source. Please take a look to the ReadMe.txt file in the directory Sourcecode/default and to the chapter 4. The result of compilation have the extensions .hex and .eep . Usually the names will be TransistorTester.hex and TransistorTester.eep . The .hex file contains the data for the program memory (flash) of the ATmega processor. The .eep file contains the data for the EEprom memory of the ATmega. Both data files must be loaded to the correct memory.

Additionally the operating state of the ATmega processor must be programmed with the “fuses”. If you can use my Makefile and additionally the program avrdude, you need no exact knowledge of the details about the fuses. You have only to type “make fuses” if you have no crystal or “make fuses-crystal” if you have installed the 8MHz crystal to your printed board. With the ATmega168 series of the microcontroller you can also use “make fuses-crystal-lp” to use a crytal with the low power mode. Never choose the crystal mode of clock generation, if you don’t have installed the 8MHz crystal. If you are not shure with the fuses, leave them as default set by manufactor and first bring the the tester to operation in this mode. Maybe your program runs too slow, if you use program data compiled for 8MHz operation, but you can correct this later! But a wrong set of fuses may inhibit later ISP-programming.

2.4 Troubleshooting

In most cases of problems you will miss the text output to the LCD-display. At first you should check, if the LED was illuminated weak, if you release the Test button.

Power does not switch on. If the LED is without light and the VCC power has correct 5V voltage during holding the Test button, the microcontroller does not switch the power correctly. The microcontroller should hold the power by switching the PD6 output to 5V, which is usually done as one of the first actions. If you hold the Test key pressed, the power is switched on anyway. So you can check the value of VCC power and additionally the voltage value of the PD6 output, if you hold the key pressed. If VCC voltage has correct value (5V), but PD6 voltage is below 4V, your microcontroller does not start the program. In this case you should

check if the microcontroller flash has been loaded with proper data for your installed type and if ATmega is correctly configured with the fuses. If your ATmega put the PD6 output to 5V and the power does not stay if you release the Test key, it is more difficult to find the reason. First you can shorten the LED and try again. If your Tester now starts, your LED may be faulty or mounted with wrong polarity. If this is not the reason, the current amplification factor of your T3 transistor (BC557C) is insufficient. The current to the base of T3 is lower in the microcontroller state as in the “key pressed” state.

Nothing is readable on the LCD display Check the voltage at the contrast pin at the LCD display (pin 3). Adjust to correct value specified in the data sheet of your display and optimize by viewing. If you have a high temperature display type, you must provide a negative contrast voltage for operation. In this case you can use the ICL 7660 device for generating a negative voltage from positive 5V.

If there is no output readable on the LCD and the background light is on, you should disconnect the power and check all four data plus the two control signal connections. If all connection are well, the only reason I see is a uncorrect timing of control signals. This can be caused by a slower LCD controller than expected by the software or the ATmega software runs at wrong clock speed. Please check for which clock speed your programming data was compiled and if the fuses of the ATmega are correct set to that speed. You find the clock parameter in the corresponding Makefile.

Something but not all is readable on the LCD display Check if the .EEP data are loaded to the EEprom memory of ATmega. If all data are loaded correctly, you should check the clock speed of your programming data (Makefile) and ATmega processor settings (fuses).

Measurement is slow and Capacitors are measured about 8 times too small You run software compiled for 8MHz clock at real clock speed of 1MHz. Please set the fuses of the ATmega correctly.

Measurement has strangely values Check if your programmer is still connected to the ISP-plug. The ISP interface should be disconnected for measuring. Very often the reason of wrong measurements is the use of software compiled with the AUTOSCALE_ADC option and with the option NO_REF_CAP, but the capacitor at the AREF pin has still a value of 100nF. Wrong assembly of components or remaining soft solder flux can disturb the measurements too. Please check with the selftest function of your TransistorTester software if possible. For the details see Chapter 5.5.

Otherwise inspect your board visually and check the resistor values with a ohmmeter. You can use the pins of the ATmega for this check, for example to check the R1 you can measure between pin 23 and pin 14. Take a look at the circuit diagram 2.1 for details. There is no need to remove the microcontroller, only battery or power supply should be removed before.

Chapter 3

Instructions for use

3.1 The measurement operation

Using of the Transistor-Tester is simple. Anyway some hints are required. In most cases are wires with alligator clips connected to the test ports with plugs. Also sockets for transistors can be connected. In either case you can connect parts with three pins to the three test ports in any order. If your part has only two pins, you can connect this pins to any two of the tree test ports. Normally the polarity of part is irrelevant, you can also connect pins of electrolytical capacitors in any order. The measurement of capacity is normally done in a way, that the minus pole is at the test port with the lower number. But, because the measurment voltage is only between 0.3 V and at most 1.3 V, the polarity doesn't matter. When the part is connected, you should not touch it during the measurement. You should put it down to a nonconducting pad if it is not placed in a socket. You should also not touch to the isolation of wires connected with the test ports, the measurement results can be affected. Then you should press the start button. After displaying a start message, the measurement result should appear after two seconds. If capacitors are measured, the time to result can be longer corresponding to the capacity.

How the transistor-tester continues, depends on the configuration of the software.

Single measurement mode If the tester is configured for single measurement mode, the tester shut off automatical after displaying the result for 10 seconds for a longer lifetime of battery. During the display time a next measurement can be started by pressing the start button. After the shut off a next measurement can be started too of course. The next measurement can be done with the same or another part.

Endless measurement mode A special case is the configuration without automatical shut off. This configuration is normally only used without the transistors for the shut off function. A external off switch is necessary for this case. The tester will repeat measurements until power is switched off.

Multi measurement mode In this mode the tester will shut down not after the first measurement but after a configurable series of measurements. In the standard case the tester will shut down after five measurements without found part. If any part is identified by test, the tester is shut down after double of five (ten) measurements. A single measurement with unknown part after a series of measurement of known parts will reset the counter of known measuerements to zero. Also a single measurement of known part will reset the counter of unknown measurements to zero. This behavior can result in a nearly endless series of measurements without pressing the start button, if parts are disconnected and connected in periodical manner.

In this mode there is a special feature for the display period. If the start button is pressed only short for switching on the tester, the result of measurement ist only shown for 5 seconds. Buf if

you press and hold the start button until the first message is shown, the further measurement results are shown for 14 seconds. The next measurement can started earlier by pressing the start button during the displaying of result.

3.2 Selftest and Calibration

If the software is configured with the selftest function, the selftest can be started by connecting all three test ports together and pushing of the start button. In this case all of the documented tests in the Selftest chapter 5.5 will be done. The repetition of the tests can be avoided, if the start button is hold pressed. So you can skip uninteresting tests fast and you can watch interesting tests by releasing the start button.

If the function AUTO_CAL is selected in the Makefile, there will be calibrated the internal resistance of the port output and the zero offset for the capacity measurement. It is important for the calibration task, that the connection between the three test ports is relased during test number 4. You should not touch to any of the test ports or connected cables when calibration (after test 6) is done. But the equipment should be the same used for further measurements. Otherwise the zero offset for capacity measurement is not detected correctly.

A capacitor with any capacity between $100nF$ and $20\mu F$ connected to pin 1 and pin 3 is required for the last task of calibration. To indicate that, a capacitor symbol is shown between the pin number 1 and 3, followed by the text " $\leq 100nF$ ". You should connect the capacitor not before this text is shown. With this capacitor the offset voltage of the analog comparator will be compensated for better measurement of capacity values. Additionally the gain for ADC measurements using the internal reference voltage will be adjusted too with the same capacitor for better resistor measurement results with the AUTOSCALE_ADC option.

The zero offset for the ESR measurement will be preset with the option ESR_ZERO in the Makefile. This zero offset, which is set too high in normal case, will be preset in EEPROM by the software. With every selftest the ESR zero offset will be reset to this initial value. After every ESR measurement the result will be checked for negative value (output of "ESR=0?"). In this case the zero offset will be reduced to get a zero result for next ESR measurement. With this methode the zero offset can be adjusted with a electrolytical capacitor with high capacity value and low ESR value. This learned ESR zero offset remains active after power off, but the adjust procedure to get the zero offset of ESR measurement must be done after every selftest and in this case you should always repeat the measurement some times.

3.3 special using hints

Normally the Tester shows the battery voltage with every start. If the voltage fall below a limit, a warning is shown behind the battery voltage. If you use a rechargeable 9V battery, you should replace the battery as soon as possible or you should recharge. If you use a tester with attached 2.5V precision reference, the measured supply voltage will be shown in display row two for 1 second with "VCC=x.xxV".

It can not repeat often enough, that capacitors should be discharged before measuring. Otherwise the Tester can be damaged before the start button is pressed. If you try to measure components in assembled condition, the equipment should be allways disconnected from power source. Furthermore you should be shure, that no residual voltage reside in the equipment. Every electronical equipment has capacitors inside!

If you ty to measure little resistor values, you should keep the resistance of plug connectors and cables in mind. The quality and condition of plug connectors are important, also the resistance of

cables used for measurement. The same is in force for the ESR measurement of capacitors. With poor connection cable a ESR value of 0.02Ω can grow to 0.61Ω .

You should not expect very good accuracy of measurement results, especially the ESR measurement and the results of inductance measurement are not very exact. You can find the results of my test series in chapter 5.

3.4 Components with problems

You should keep in mind by interpreting the measurement results, that the circuit of the TransistorTester is designed for small signal semiconductors. In normal measurement condition the measurement current can only reach about 6 mA. Power semiconductors often make trouble by reason of residual current with the identification and the measurement of junction capacity value. The Tester often can not deliver enough ignition current or holding current for power Thyristors or Triacs. So a Thyristor can be detected as NPN transistor or diode. Also it is possible, that a Thyristor or Triac is detected as unknown.

Another problem is the identification of semiconductors with integrated resistors. So the base - emitter diode of a BU508D transistor can not be detected by reason of the parallel connected internal 42Ω resistor. Therefore the transistor function can not be tested also. Problem with detection is also given with power Darlington transistors. We can find often internal base - emitter resistors, which make it difficult to identify the component with the undersized measurement current.

3.5 Measurement of PNP and NPN transistors

For normal measurement the three pins of the transistor will be connected in any order to the measurement inputs of the TransistorTester. After pushing the start button, the Tester shows in row 1 the type (NPN or PNP), a possible integrated protecting diode of the Collector - Emitter path and the sequence of pins. The diode symbol is shown with correct polarity. Row 2 shows the current amplification factor ($B=...$) and the Base - Emitter threshold voltage. You should know, that the Tester can measure the amplification factor with two different circuits, the common Emitter and the common Collector circuit (Emitter follower).

With the common Emitter circuit the tester has only two alternative to select the base current:

1. The 680Ω resistor results to a base current of about 6.1mA. This is too high for low level transistors with high amplification factor, because the base is saturated. Because the collector current is also measured with a 680Ω resistor, the collector current can not reach the value with the amplification factor higher value. The software version of Markus F. has measured the Base - Emitter threshold voltage in this circuit ($U_f=...$).
2. The $470k\Omega$ resistor results to a base current of only $9.2\mu A$. This is very low for a power transistor with low current amplification factor. The software version of Markus F. has identified the current amplification factor with this circuit ($hFE=...$).

The software of the Tester figure out the current amplification factor additionally with the common Collector circuit. The higher value of both measurement methods is reported. The common collector circuit has the advantage, that the base current is reduced by negative current feedback corresponding to the amplification factor. In most cases a better measurement current can be reached with this method for power transistors with the 680Ω resistor and for Darlington Transistors with $470k\Omega$ resistor. The reported Base - Emitter threshold voltage U_f is now measured with the same

current used for determination of the current amplification factor. However, if you want to know the Base - Emitter threshold voltage with a measurement current of about 6mA, you have to disconnect the Collector and to start a new measurement. With this connection, the Base - Emitter threshold voltage at 6 mA is reported. The capacity value in reverse direction of the diode is also reported. Of course you can also analyse the base - collector diode.

3.6 Measurement of JFET and D-MOS transistors

Because the structure of JFET type is symmetrical, the Source and Drain of this transistores can not be differed. Normally one of the parameter of this transistor is the current of the transistor with the Gate at the same level as Source. This current is often higher than the current, which can be reached with the measurement circuit of the TransistorTester with the 680Ω resistor. For this reason the 680Ω resistor is connected to the Source. Thus the Gate get with the growing of current a negative bias voltage. The Tester reports the Source current of this circuit and additionally the bias voltage of the Gate. So various models can be differed. The D-MOS transistors (depletion type) are measured with the same methode.

Chapter 4

Configuring the TransistorTester

The complete software for the TransistorTester is available in source code. The compilation of modules is controlled with a Makefile. The development was done at the Ubuntu Linux operating system with the GNU toolchain (gcc version 4.5.3). It should be possible to use other Linux operating systems without problems. To load the compiled data to the flash memory or the EEPROM memory, the tool avrdude (version 5.11svn) was taken by the Makefile, if you call “make upload”. The program avrdude is available for Linux and Windows operating system. The gnu C-compiler gcc is also taken by the AVR studio software and by the WinAVR [16],[17] software at the Windows operating system. You can load the program data (.hex and .eep) also with other tools to the ATmega, but only my Makefile version takes care to load the correct data to the choosed processor. Avrdude loads only data to the ATmega if the Signature Bytes of the connected ATmega is identical to the choosed one. If you alter the Makefile, all the software will be compiled new, if you call a “make” or “make upload” command. The software compiled for a ATmega8 does not run on a ATmega168. The software compiled for a ATmega328 does not run on the ATmega168! A exeption from this rule is the software compiled for ATmega168, this data can also be used for a ATmega328 without changes. Be careful, if you don’t use my Makefile.

With the correct options set, my software runs on the unchanged hardware of Markus F. (PARTNO=M8, NO option NO_AREF_CAP and NO PULLUP_DISABLE option). The clock rate can also be set to 8 MHz with fuses, no crystal is required!

The following options in the Makefile are avaiable to configure the software for your Tester.

PARTNO describes the target processor:

m8 = ATmega8
m168 or m168p = ATmega168
m328 or m328p = ATmega328
example: PARTNO = m168

ULLANGUAGE specifies the favored Language

LANG_ENGLISH, LANG_GERMAN, LANG_POLISH, LANG_CZECH, LANG_SLOVAK, LANG_SLOV
and LANG_DUTCH is currently avaiable
example: ULLANGUAGE = LANG_ENGLISH

LCD_CYRILLIC is only needed for a LCD-display with cyrillic character set. The μ and Ω character is not avaiable with the cyrillic character set. If you specify this option, both characters are loaded to the LCD with software.

example: CFLAGS += -DLCD_CYRILLIC

STRIP_GRID_BOARD This option adapts the software to a changed port D connection for strip grid printed boards. You can find the details in the chapter hardware 2.1.

WITH_SELFTEST If you specify this Option, software will include a selftest function. Selftest will be started, if you connect all three probes together and start measurement.

example: CFLAGS += -DWITH_SELFTEST

AUTO_CAL The zero offset for capacity measurement and the port output resistor values will be written additionally to the EEprom with the selftest routine. Additionally the offset voltage of the analog comparator (REF_C_KORR) and the voltage offset of the internal reference voltage (REF_R_KORR) will be measured automatically, if you connect a capacitor with a capacity value between $100nF$ and $20\mu F$ to pin 1 and pin 3 after measurement of capacity zero offset. All found values will be written to EEprom and will be used for further measurements automatically.

example: CFLAGS += -DAUTO_CAL

FREQUENCY_50HZ At the end of selftest a 50 Hz Signal will be generated on Port 2 and Port 3 for up to one minute.

example: CFLAGS += -DFREQUENCY_50HZ

CAP_EMPTY_LEVEL This option defines the voltage level for discharged capacitor (mV units). You can set the level to higher value as 3mV, if the tester does not finish discharging of capacitors. In this case the tester ends after longer time with the message "Cell!".

example: CFLAGS += -DCAP_EMPTY_LEVEL=3

WITH_AUTO_REF specifies, that reference voltage is read to get the actual factor for capacity measuring of low capacity values (below $40\mu F$).

example: CFLAGS += -DWITH_AUTO_REF

REF_C_KORR specifies a offset for readed reference voltage in mV units. This can be used to adjust the capacity measurement of little capacitors. A correction value of 10 results to about 1 percent lower measurement results. If the option AUTO_CAL is selected together with the WITH_SELFTEST option, the REF_C_KORR will be a offset to the measured voltage difference of the test capacitor and the internal reference voltage.

example: CFLAGS += -DREF_C_KORR=14

C_H_KORR specifies a correction value for the measurement of big capacitor values. A value of 10 results to 1 percent lower measurement results.

example: CFLAGS += -DC_H_KORR=10

AUTOSCALE_ADC enables the automatic scale switchover of the ADC to either VCC or internal reference. Internal reference gives a 2.56V scale for ATmega8 and a 1.1V scale for other processors.

example: CFLAGS += -DAUTOSCALE_ADC

ESR_ZERO defines a zero offset for ESR measurements. This zero offset will be subtracted from all ESR measurements. If the ESR measurement results to a negative value, the text "ESR=0?" is displayed and the zero offset in the EEprom memory will be corrected. This corrected zero offset will be used for further measurements until it is resetted to initial value by selftest. If your measured ESR values always too high, you should select a higher ESR_ZERO value.

Example: CFLAGS += -DESR_ZERO=29

NO_AREF_CAP tells your Software, that you have no capacitor ($100nF$) installed at pin AREF (pin 21). This enables a shorter wait-time for the AUTOSCALE_ADC scale switching of the ADC. A $1nF$ capacitor was tested in this mode without detected errors. Figure 4.1a and 4.1b show the switching time with a $1nF$ capacitor. As you can see the switching from 5V to 1.1V

is much slower than switching back to 5V. If you have still installed the $100nF$, switching time will be about factor 100 longer!

example: CFLAGS += -DNO_AREF_CAP

REF_R_KORR specifies a offset for the internal ADC-reference voltage in mV units. With this offset a difference by switching from VCC based ADC reference to internal ADC reference for resistor measurement can be adjusted. If you select the AUTO_CAL option of the selftest section, this value is only a additionally offset to the found voltage difference in the AUTO_CAL function.

example: CFLAGS += -DREF_R_KORR=10

OP_MHZ tells your software at which Clock Frequency in MHz your Tester will operate. The software is tested only for 1 MHz, 8MHz and additionally 16MHz. The 8MHz operation is recommended for better resolution of capacity and inductance measurement.

example: OP_MHZ = 8

USE_EEPROM specifies if you wish to locate fix text and tables in EEprom Memory. Otherwise the flash memory is used. Recommended is to use the EEprom (option set).

example: CFLAGS += -DUSE_EEPROM

EBC_STYLE specifies, that the output of transistor pin layout is done with format “EBC=...” or “GDS=...”. This way of output save program memory for the ATmega. Without this option the layout is shown with the format “123=...”, where every point represent a E (Emitter), B (Base) or C (Collector). For FET transistors every point can be a G (Gate), D (Drain) or S (Source).

Example: CFLAGS += EBC_STYLE

PULLUP_DISABLE specifies, that you don't need the internal pull-up resistors. You must have installed a external pull-up resistor at pin 13 (PD7) to VCC, if you use this option. This option prevents a possible influence of pull-up resistors at the measuring ports (Port B and Port C).

example: CFLAGS += -DPULLUP_DISABLE

ANZ_MESS this option specifies, how often an ADC value is read and accumulated. You can select any value between 5 and 200 for building mean value of one ADC measurement. Higher values result to better accuracy, but longer measurement time. One ADC measurement with 44 values takes about 5ms.

example: CFLAGS += -DANZ_MESS=25

POWER_OFF This option enables the automatic power off function. If you don't specify this option, measurements are done in a loop infinitely until power is disconnected with a ON/OFF switch. If you have the tester without the power off transistors, you can deselect the option POWER_OFF.

If you have NOT selected the POWER_OFF option with the transistors installed, you can also shut down the tester. During displaying the measurement result you should hold the start key pressed for several seconds until the "Timeout" message is displayed. If you then release the key, the tester will be shut off.

You can also specify, after how many measurements without a founded part the tester will shut down. The tester will also shut down the power after twice as much measurements are done in sequence without a single failed part search. If you have forgotten to unconnect a test part, total discharging of battery is avoided. Specify the option with a form like CFLAGS += -DPOWER_OFF=5 for a shut off after 5 consecutive measurements without part found. Also 10 measurements with any founded part one after another will shut down. Only if any

sequence is interrupted by the other type, measurement continues. The result of measurement stay on the display for 14 seconds for the single measurement, for the multiple measurement version display time is reduced to 5 seconds (set in config.h). If the start key is pressed a longer time on power on time, the display time is also 14 seconds for the multiple measurement. The maximum value is 255 (CFLAGS += -DPOWER_OFF=255).

example 1: CFLAGS += -DPOWER_OFF=5

example 2: CFLAGS += -DPOWER_OFF

BAT_CHECK enables the Battery Voltage Check. If you don't select this option, the version number of software is output to the LCD instead. This option is usefull for battery powered tester version to remember for the battery change.

example: CFLAGS += -DBAT_CHECK

BAT_OUT enables Battery Voltage Output on LCD (if BAT_CHECK is selected). If your 9V supply has a diode installed, use the BAT_OUT=600 form to specify the threshold voltage (mV) of your diode to adjust the output value. Also the voltage loss of transistor T3 can be respected with this option. threshold level does not affect the voltage checking levels (BAT_POOR).

example 1: CFLAGS += -DBAT_OUT=300

example 2: CFLAGS += -DBAT_OUT

BAT_POOR sets the poor level of battery voltage to the specified 100mV (1/10 Volt) value. The warning level of battery voltage is always 1V higher than the specified poor level. Setting the poor level to low values such as 5.4V is not recommended for rechargeable 9V batteries, because this increase the risk of battery damage by the reason of the deep discharge! If you use a rechargeable 9V Battery, it is recommended to use a Ready To Use type, because of the lower self-discharge.

example for low drop regulator (5.4V): CFLAGS += -DBAT_POOR=54

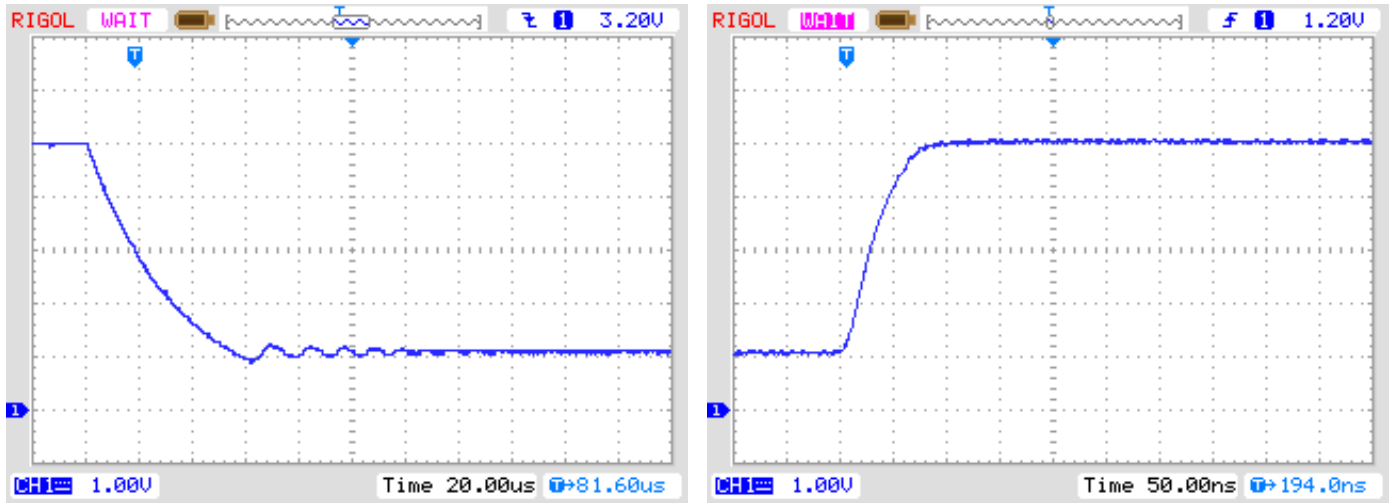
example for 7805 type regulator (6.4V): CFLAGS += -DBAT_POOR=64

PROGRAMMER select your programmer type for avrdude interface program. The correct selection of this option is needed, if you use the "make upload" or "make fuses" call of this Makefile. For further information please look to the manual pages of avrdude and online documentation [12].

example: PROGRAMMER=avrisp2

PORT select the port where avrdude can reach your microcontroller (atmega). For further information please look to the manual pages of avrdude.

example: PORT=usb



(a) from 5V to 1.1V

(b) from 1.1V to 5V

Figure 4.1: AREF switching with a $1nF$ Capacitor

Additional parameters can be set in the files `transistortester.h` and `config.h`. The file `transistortester.h` contains global variables and defines the port / pin constellation and the resistor values used for measurement. The file `config.h` specifies parameter for different processor types, wait times and the clock frequency of the ADC. Normally there is no reason to change these values.

Chapter 5

Description of the measurement procedures

The simplified schematic of a Input/Output-Port pin of the ATmega is shown in figure 5.1. The PUD switch isolates all “pull up” resistors of the ATmega. The output of a pin can be switched off with the DD switch. The Input can operate regardless to the state of the switch DD. The PORT switch usually defined the output level, but also switches the pull up resistor. Because the Switches PORT and DD can not be changed at the same time but only one after another, the pull up resistors can disturb the measurement. Therefore I prefer to disable the pull up resistors with the PUD switch. Of course all the switches are electronic type and the resistors 19Ω and 22Ω are approximated values.

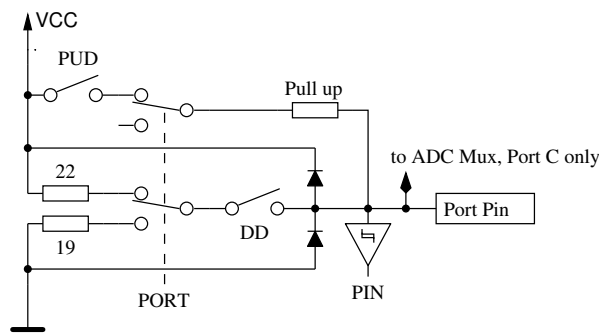


Figure 5.1: simplified diagram of each ATmega port pin

Every of the three terminal probes of your Transistor Tester is build with three ATmega port pins, which is shown as simplified diagram for the terminal probe TP2 (middle of three pins) in figure 5.2.

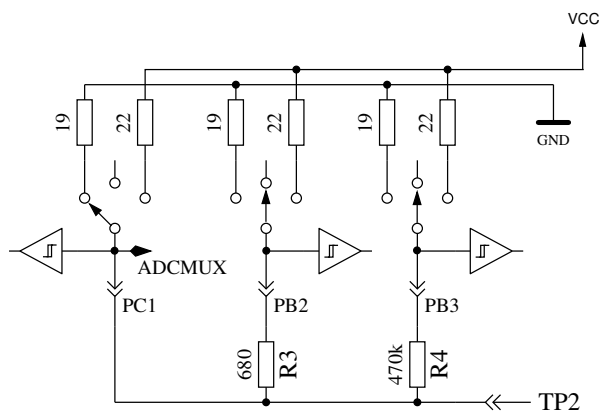


Figure 5.2: simplified circuit of each measurement terminal probe TP

Every test pin (measurement port) can be used as digital or analog input. This measurement capability is independent of using the port as output. Every test pin can be switched to output and in this mode it can be directly connected to GND (0V) or VCC (5V), or it can be connected via a 680Ω resistor or a $470k\Omega$ resistor to either GND or VCC. Table 5.1 shows all possible combination of measurements. Notice, that the positive state can be switched directly to VCC (Port C) or it can be connected with the 680Ω resistor to VCC (Port B). The same possibility has the negative state of terminal probe to the GND side. The test state means, that probe can be open (Input), connected with the $470k\Omega$ resistor to VCC or GND, or that the probe can be connected with the 680Ω resistor to VCC or GND.

	state pin 1	state pin 2	state pin 3
1.	positive	negative	test
2.	positive	test	negative
3.	test	negative	positive
4.	test	positive	negative
5.	negative	test	positive
6.	negative	positive	test

Table 5.1: all combinations of measurement

If the capacitor measuring is configured for the tester, the tester will try to discharge the capacitors connected at all test pins. If discharge will fail, that means the remaining voltage is too high, the discharging will be aborted after about 12 seconds with the message "Cell!". This can also happen, if no capacitor is connected to any test pin. The cause for this can be, that the cut-off voltage is chosen too low for this ATmega. You can choose a higher voltage with the Makefile option CAP_EMPTY_LEVEL.

5.1 Measurement of Semiconductors

One probe pin is assumed to be the negative side of the component. Another pin is assumed to be the positive side of the component. For a first test, the components positive side is directly connected to VCC. The negative side is connected with the 680Ω resistor to GND. The test probe (third pin, also called TriStatePin) is first connected with the 680Ω resistor for 10 ms to GND. The voltage of the negative probe pin is read, during the TriStatePin is switched to Input (High Impedance). It is assumed that the tested part can be a N-Channel MOSFET and the gate should be discharged. If the readed voltage is above 976mV, the next test assume, that the tested part can also be a P-Channel MOSFET and for this a 10ms switch of the TriStatePin with the 680Ω resistor to the VCC side is done. Also for this case the voltage at the negative Probe pin is read with a currentless TriStatePin. If the voltage of the negative pin is greater than 92mV, additional tests are made to differ N-Channel JFET or D-MOSFET (depletion) and P-Channel JFET or P-MOSFET. The MOSFET versions can be differed by the missing of gate current in any state of the TriStatePin.

To get parameters of the depletion types, they will be measured with a 680Ω resistor at the source pin, as shown in figure 5.3 . This measurement will be done instead of the usually measurement of current with the gate hold at source level, because the I_{DSS} current of the FET transistor can often not be reached with the relative high resistance of the 680Ω resistor.

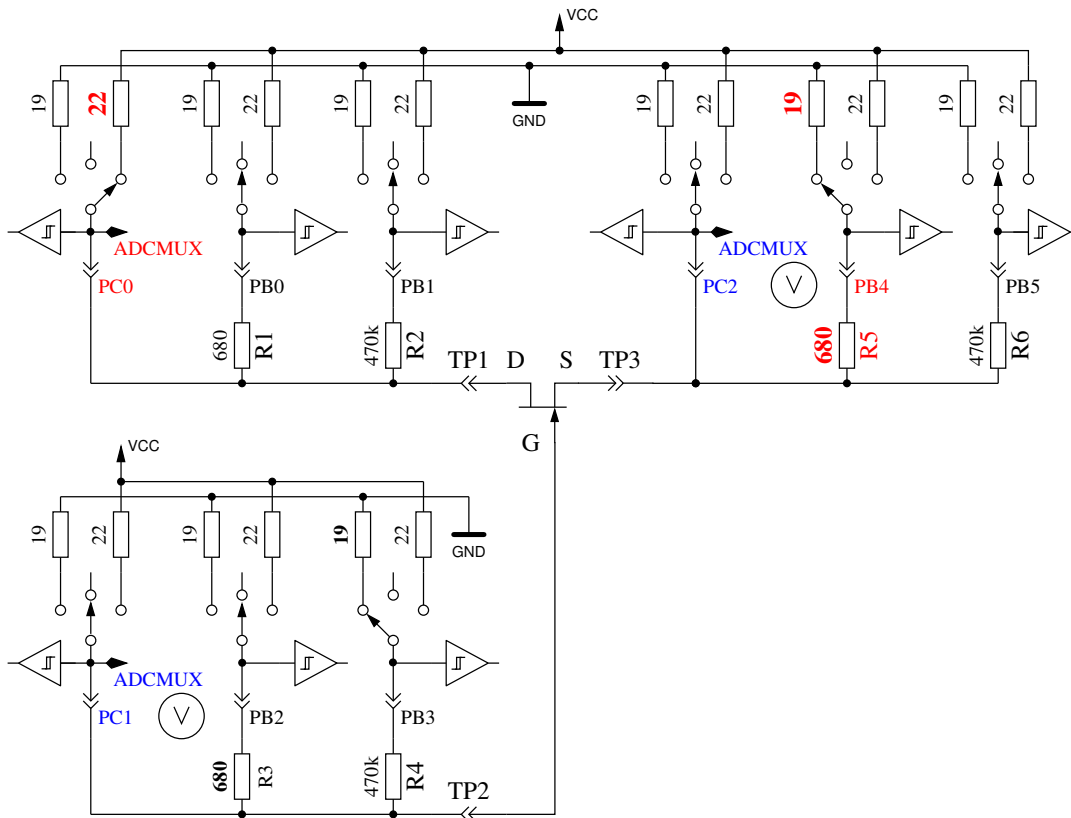


Figure 5.3: Measurement of the Gate-Source voltage and Source current of a N-JFET transistor

If the component has no current between positive probe and negative probe without signal at the TriStatePin, the next tests are specified in the next section 5.1.1. If current was detected, the next test is described in the diode section 5.1.3.

5.1.1 Measurement of PNP Transistor or P-Channel-MOSFET

First the current amplification factor is measured with common collector for the assumed PNP transistor. The measuring situation is shown in figure 5.4. If the measured voltage at the Base (U_B)

is above 9mV with the 680Ω resistor, the hFE is build as $hFE = \frac{UE-UB}{UB}$. The voltage UE is the difference of the Emitter-voltage to VCC. The difference between the 22Ω and 19Ω resistors are not respected. If the UB voltage is below 10mV, the measurement is done with the 470kΩ resistor at the base. In this case the current amplification factor is build as $hFE = \frac{UE \cdot 470000}{UB \cdot (680 + 22)}$.

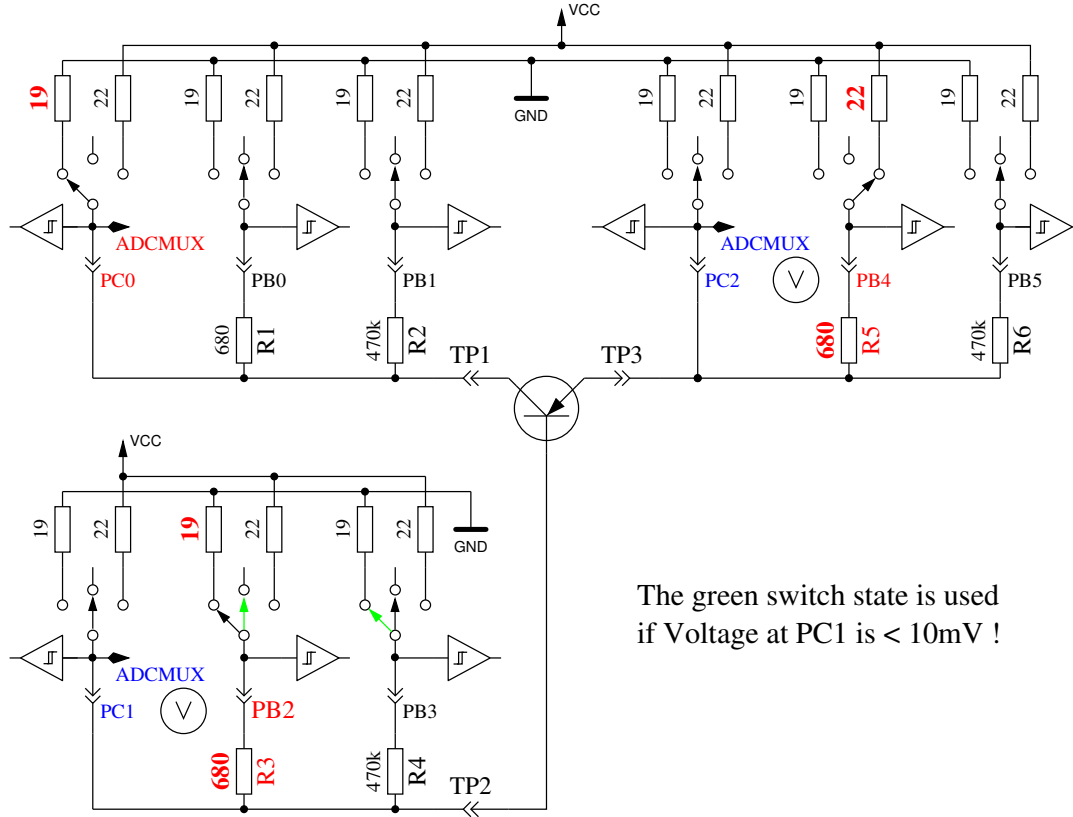


Figure 5.4: hFE measurement of PNP transistor with common collector circuit

Next the tests with common emitter are done for the assumed PNP transistor. The positive side of component is now direct connected to VCC, the negative side 680Ω resistor is connected to GND as shown in Figure 5.5. If the negative side of component has a voltage of above 3.4V, when the base side 680Ω resistor was connected to GND, it must be a PNP transistor or a P-Channel FET. This can be easy find out by analysing the base voltage. If the base voltage is greater 0.97V, it must be a PNP. For measuring the current amplification factor, the 470kΩ resistor is taken as Base resistor instead of the 680Ω. The current amplification factor is build by $hFE = \frac{UC \cdot 470000}{UB \cdot (680 + 19)}$. The higher current amplification factor is assumed to be the right one, this one or the one found with the common collector circuit. The values found for the PNP are only valid, if a second set of measurements is done. In order to prevent detecting the PNP in the inverse mode (collector and emitter are swapped), the measurement with the higher current amplification is taken as the right one. If base voltage is lower than 0.97V, it must be a P-E-MOS. In this case the gate threshold voltage is measured by switching the gate slowly with the 470kΩ resistor up and down, waiting for a digital input signal change of the Drain side and then read the voltage of the gate pin.

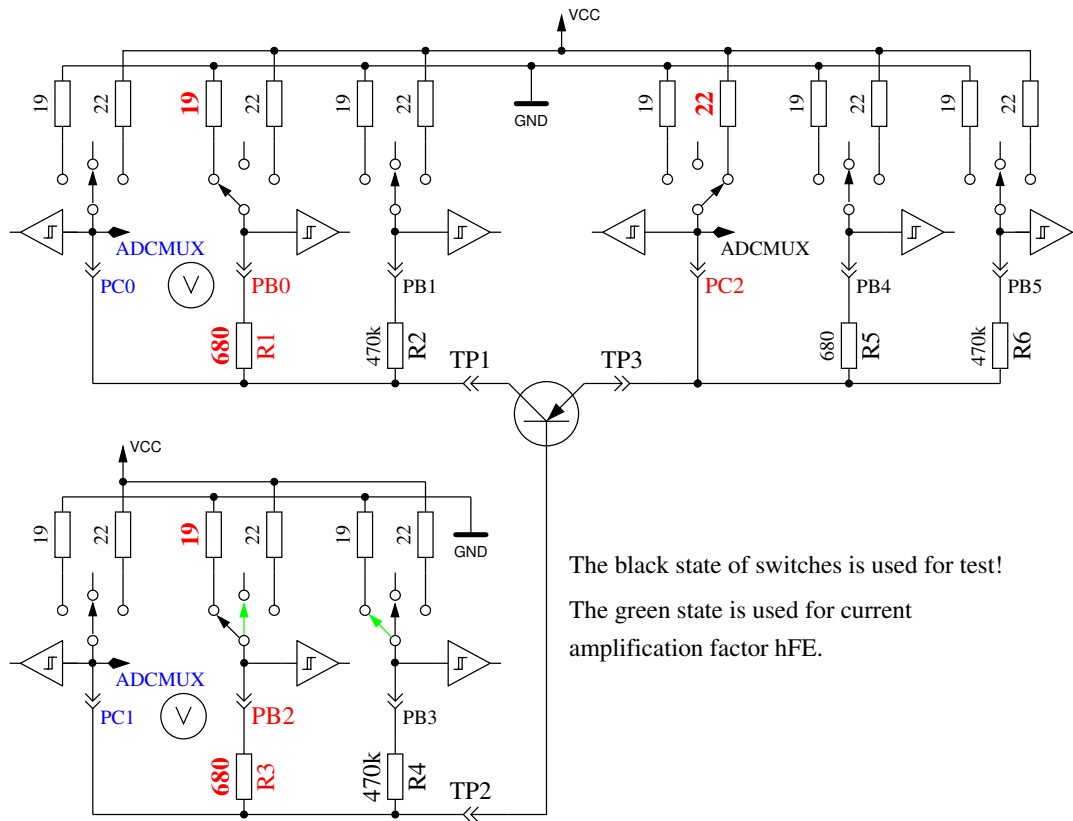


Figure 5.5: test and hFE measurement of PNP transistor with common emitter circuit

5.1.2 Measurement of NPN Transistor or N-Channel-MOSFET

The measuring of NPN-Transistors begin in the same way as PNP-Transistors with measuring the current amplification factor in the common collector circuit. First measurement is done with a 680Ω base resistor switched to VCC. If the voltage at the base resistor ist too low, the $470k\Omega$ resistor is taken instead. Measurement then continues with the common emitter circuit as shown in figure 5.6.

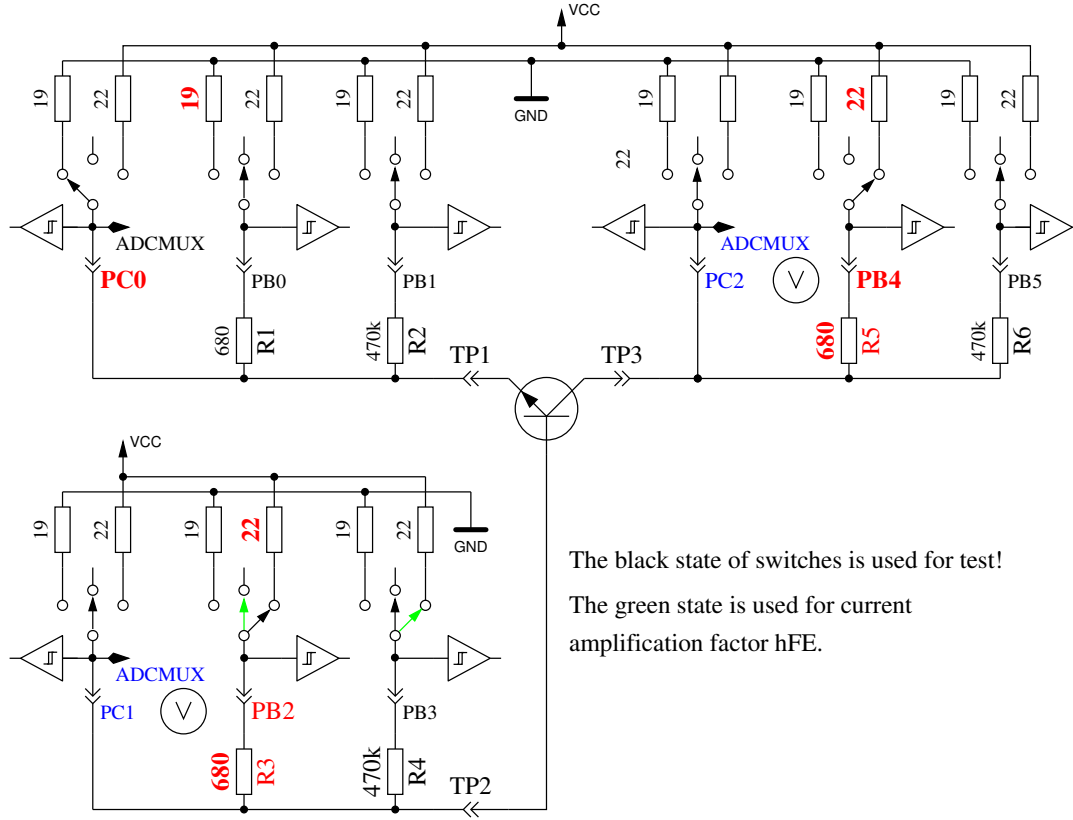


Figure 5.6: test and hFE measurement of NPN transistor with common emitter circuit

If the voltage of collector sinks below 1.6V, when the 680Ω base resistor is connected to VCC, it must be a NPN, N-Channel MOSFET or Thyristor/Triac. With two simple tests a Thyristor or Triac can be identified. If the gate pin resistor is connected for 10ms to GND and then made currentless, the current at the anode should stay. If then the anode resistor is short connected to GND and reconnected to VCC, the Thyristor should not trigger again (no current). Please keep in mind, that only low power Thyristors can be tested, because the holding current of the tester can reach only 6mA. If both tests attest a Thyristor, further tests with reverse polarity are done to exclude or confirm a Triac.

If neither Thyristor nor Triac could be confirmed, it can be a NPN or N-Channel E-MOSFET. The Base voltage of a NPN Transistor will be near the Emitter voltage, so this type can be identified definitely. The current amplification factor in the common emitter circuit is build by $hFE = \frac{(VCC-UC) \cdot 470000}{(VCC-UB) \cdot (680+22)}$. If the voltage of the Base or better Gate shows, that there is no or little current, part will be a N-Channel E-MOS (Enhancement MOSFET). In this case the threshold voltage is measured by switching the Gate slowly with the 470kΩ resistor to VCC and GND, waiting for a digital input signal change of the Drain side and then read the voltage of the Gate pin. This measurement is done eleven times with ADC results accumulated as shown in Figure 5.7. The result is multiplied by four and divided by 9 to get the voltage in mV resolution.

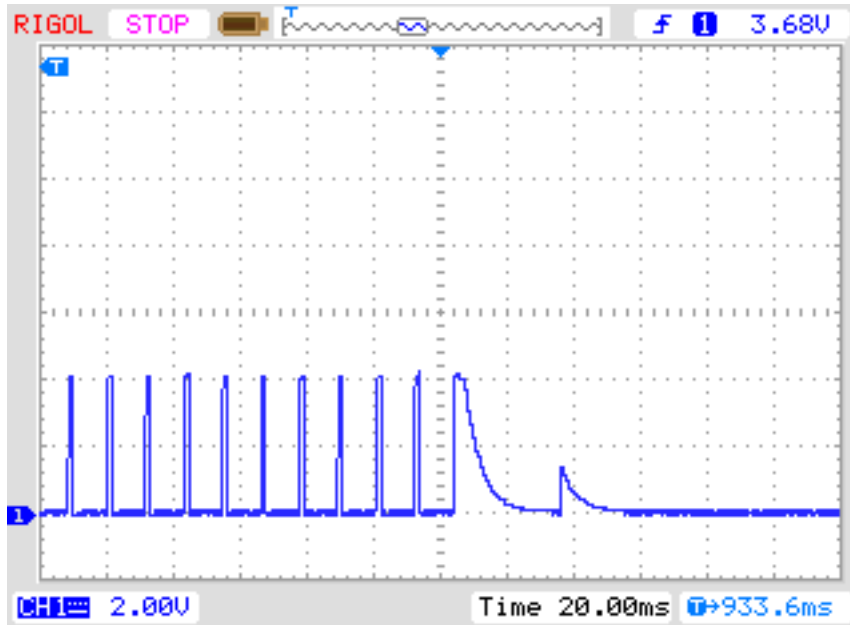


Figure 5.7: measuring of threshold voltage of N-Channel-MOSFET

5.1.3 Measurement of Diodes

If current is detected with the pre-tests, the behavior of the part will be checked to be a diode. The flow voltage with the 680Ω resistor must be between $0.15V$ and $4.64V$. The flux voltage with the 680Ω must be greater than 1.125 times the flux voltage with the $470k\Omega$ resistor and eight times the flux voltage with the $470k\Omega$ must be greater than the flux voltage with the 680Ω resistor. I hope, that this behavior is always a diode.

5.1.4 Results of different measurements

The following three tables shows results of different test probes with one ATmega8 processor and two different software versions of a ATmega168 processor. The measurement of the inverse capacity value for the double diode MBR4045PT is only possible with cooling. This will be caused by high residual current of this $40A$ diode. Also the capacity value of the inverse base emitter diode of the germanium transistor AC128 can only be measured with cooling.

Diode Type	Mega8@8MHz signature 1E9307 WITH_AUTO_REF	Mega168 @8MHz signature 1E9406	Mega168 @8MHz signature 1E9406 WITH_AUTO_REF AUTOSCALE_ADC
1N4148	Diode, 715mV, 1pF	Diode, 721mV, 0pF	Diode, 714mV, 0pF
1N4150	Diode, 665mV, 1pF	Diode, 672mV, 1pF	Diode, 667mV, 0pF
BA157	Diode, 619mV, 19pF	Diode, 625V, 20pF	Diode, 620mV, 18pF
BY398	Diode, 538mV, 16pF	Diode, 541mV, 16pF	Diode, 541mV, 15pF
1N4007	Diode, 650mV, 13pF	Diode, 660mV, 13pF	Diode, 655mV, 10pF
LED green	Diode, 1.96V, 5pF	Diode, 1.95V, 6pF	Diode, 1.95V, 4pF
ZPD2,7	2xDi, 743mV, 2.53V	2xDi, 743mV, 2.53V	2xDi, 736mV, 2.52V
BU508A B+E	Diode, 609mV, 5.15nF	Diode, 614mV, 5.30nF	Diode, 609mV, 5.28nF
BU508A B+C	Diode, 582mV, 256pF	Diode, 589mV, 264pF	Diode, 587mV, 260pF
AC128 B+E	Diode, 272mV, 0pF	Diode, 277mV, 0pF	Diode, 273mV, 0pF
AC128 B+E		cooled	Diode, 349mV, 140pF
MBR20100CT	2xDi, 337mV, 337mV	2xDi, 341mV, 341mV	2xDi, 340mV, 338mV
MBR20100CT	Diode, 337mV, 345pF	Diode, 341mV, 360pF	Diode, 338mV, 354pF
MBR4045PT cooled	Diode, 243mV, 1.80nF	Diode, 239mV, 1.98nF	Diode, 235mV, 1.95nF
SF38G	Diode, 519mV, 107pF	Diode, 523mV, 108pF	Diode, 521mV, 108pF

Table 5.2: measurement results of diode testing

Transistor Type	Mega8@8MHz signature 1E9307 WITH_AUTO_REF	Mega168 @8MHz signature 1E9406	Mega168 @8MHz signature 1E9406 WITH_AUTO_REF AUTOSCALE_ADC
BU508A	NPN, B=9, 602mV	NPN, B=9, 599mV	NPN, B=9, 599mV
2N3055	NPN, B=20, 553mV	NPN, B=21, 551mV	NPN, B=21, 551mV
BC639	NPN, B=180, 628mV	NPN, B=215, 633mV	NPN, B=215, 630mV
BC640	PNP, B=216, 635mV	PNP, B=226, 639mV	PNP, B=180, 604mV
BC517	NPN, B=26.1k, 1.20V	NPN, B=25.7k, 1.21V	NPN, B=26.2k, 1.22V
BC516	PNP, B=77.6k, 1.20V	PNP, B=78.7k, 1.19V	PNP, B=76.3k, 1.19V
BC546B	NPN, B=381, 659mV	NPN, B=428, 686mV	NPN, B=428, 687mV
BC556B	PNP, B=285, 689mV	PNP, B=426, 696mV	PNP, B=258, 667mV
AC128 (Ge.)	PNP, B=63, 190mV	PNP, B=63, 190mV	PNP, B=59, 189mV
BRY55/200	Thyristor	Thyristor	Thyristor
MAC97A6	Triac	Triac	Triac

Table 5.3: measurement results of bipolar transistor testing

Some results are different to the earlier results of the software of Markus Frejek. For example a darlington transistor BC517 has been measured by the older software with a hFE of 797 . and a base emitter voltage of 1438mV. This will be caused by the additional measurement of current amplification with common collector circuit. The base emitter voltage is measured by the older Version as separate diode test with 1438mV. Now the base emitter voltage is measured with the state of current amplification testing (1.20V).

FET Type	Mega8@8MHz signature 1E9307 WITH_AUTO_REF	Mega168 @8MHz signature 1E9406	Mega168 @8MHz signature 1E9406 WITH_AUTO_REF AUTOSCALE_ADC
ZVNL120A	N-E-MOS,D, 1.5V 142pF	N-E-MOS,D, 1.5V 146pF	N-E-MOS,D, 1.5V 141pF
IRF530N	N-E-MOS,D, 3.6V 1.55nF	N-E-MOS,D, 3.6V 1.56nF	N-E-MOS,D, 3.6V 1.55nF
BS170	N-E-MOS,D, 2.6V 71pF	N-E-MOS,D, 2.6V 73pF	N-E-MOS,D, 2.6V 70pF
IRL3803	N-E-MOS,D, 2.3V 9.82nF	N-E-MOS,D, 2.3V 9.82nF	N-E-MOS,D, 2.3V 9.79nF
IRFU120N	N-E-MOS,D, 4.2V 918pF	N-E-MOS,D, 4.2V 924pF	N-E-MOS,D, 4.2V 918pF
BUZ71A	N-E-MOS,D, 3.2V 710pF	N-E-MOS,D, 3.2V 718pF	N-E-MOS,D, 3.2V 712pF
ZVP2106A	P-E-MOS,D, 3.2V 117pF	P-E-MOS,D, 3.2V 121pF	P-E-MOS,D, 3.2V 116pF
IRF5305	P-E-MOS,D, 3.6V 2.23nF	P-E-MOS,D, 3.6V 2.25nF	P-E-MOS,D, 3.6V 2.24nF
BS250	P-E-MOS,D, 2.6V 46pF	P-E-MOS,D, 2.6V 48pF	P-E-MOS,D, 2.6V 46pF
IRFU9024	P-E-MOS,D, 3.5V 954pF	P-E-MOS,D, 3.6V 954pF	P-E-MOS,D, 3.5V 951pF
J310 Idss=24-60mA	N-JFET I=3.1mA Vgs=2.2V	N-JFET I=3.1mA Vgs=2.2V	N-JFET I=3.1mA Vgs=2.2V
BF256C Idss=11-18mA	N-JFET I=3.3mA Vgs=2.3V	N-JFET I=3.4mA Vgs=2.3V	N-JFET I=3.3mA Vgs=2.3V
BF245A Idss=2-6mA	N-JFET I=1.1mA Vgs=.75V	N-JFET I=1.1mA Vgs=0.74V	N-JFET I=1.1mA Vgs=0.75V
BF245B Idss=6-15mA	N-JFET I=2.4mA Vgs=1.7V	N-JFET I=2.5mA Vgs=1.7V	N-JFET I=2.4mA Vgs=1.7V
BF245C Idss=12-25mA	N-JFET I=3.8mA Vgs=2.7V	N-JFET I=3.9mA Vgs=2.7V	N-JFET I=3.8mA Vgs=2.7V

Table 5.4: measurement results of MOS transistor testing

5.2 Resistor Measurement

Each resistor is measured with four different types of measurement in one current direction. The same resistor is also tested with the same four measurement types in the other current direction. The measurement in the opposite direction is only used to identify a resistor. If mismatch between both measurements is too big, it's not a resistor.

5.2.1 Resistor Measurement with 680 Ohm Resistors

The measurement of a unknown resistor R_x is done in two ways with the build in precision 680 Ω resistors. The diagram of this measurements for test pin 1 (TP1) and test pin 3 (TP3) are simplified shown in figure 5.8 and figure 5.9 as a example of the six choices of probe combinations.

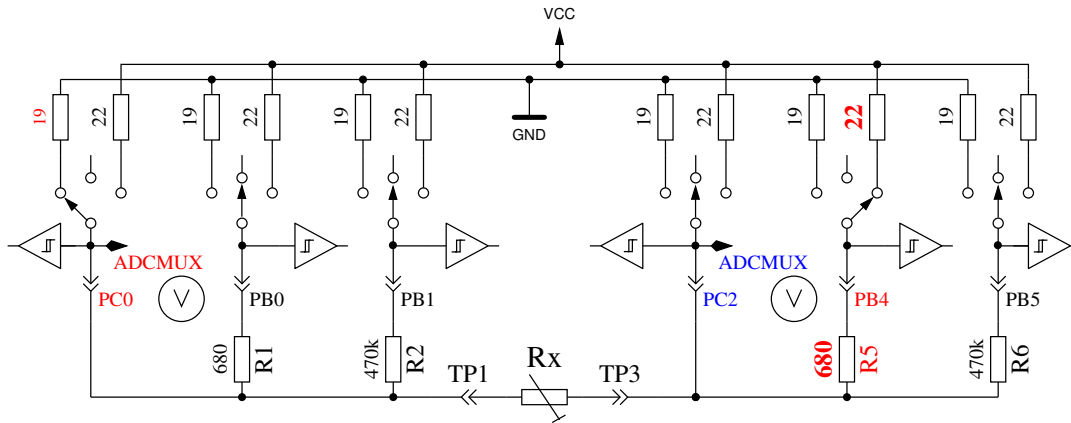


Figure 5.8: Measurement type 1 with 680 Ω

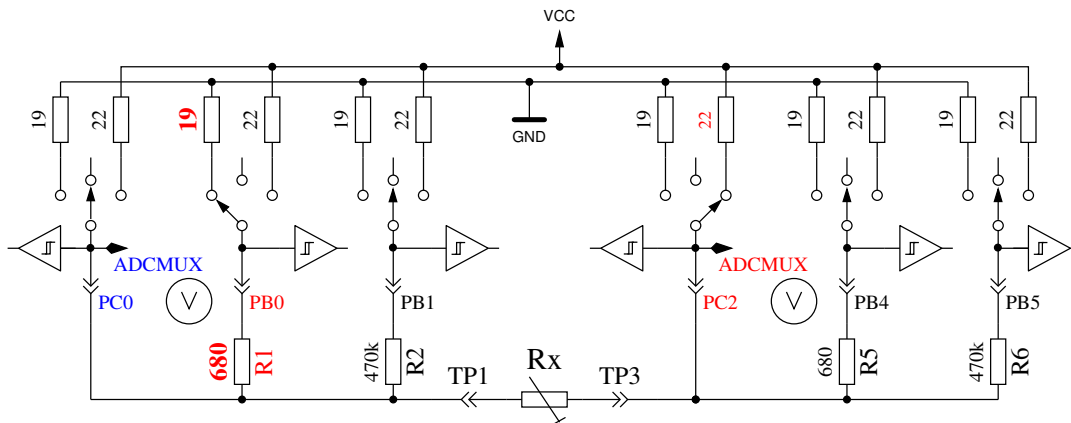


Figure 5.9: Measurement type 2 with 680 Ω

On the left side test pin 1 is shown and on the right side you can see test pin 3. In both diagrams you see, that the terminal 3 (right side) is connected to VCC, the left side is connected to GND. The direction of current flow through the resistor R_x is always the same. The values of ports switched to output are shown with red color, the values of ports used as Input are shown in blue color, the inactive ports are black. In both shown measurement types the current should have the same value, because the sum of resistor values between VCC and GND is identical (if the build in resistors are identical). Usually the measured voltage is not the same, because the sequence of resistors has changed.

The V symbol within the circle marks the ports used for voltage measurement. In both configurations the value of resistor R_x can be computed with the known resistor values and the measured voltages, if the relation of resistor R_x and the 680Ω is not too high. The theoretical voltage gradient is shown in figure 5.10, where resistor values are shown in logarithmic scale.

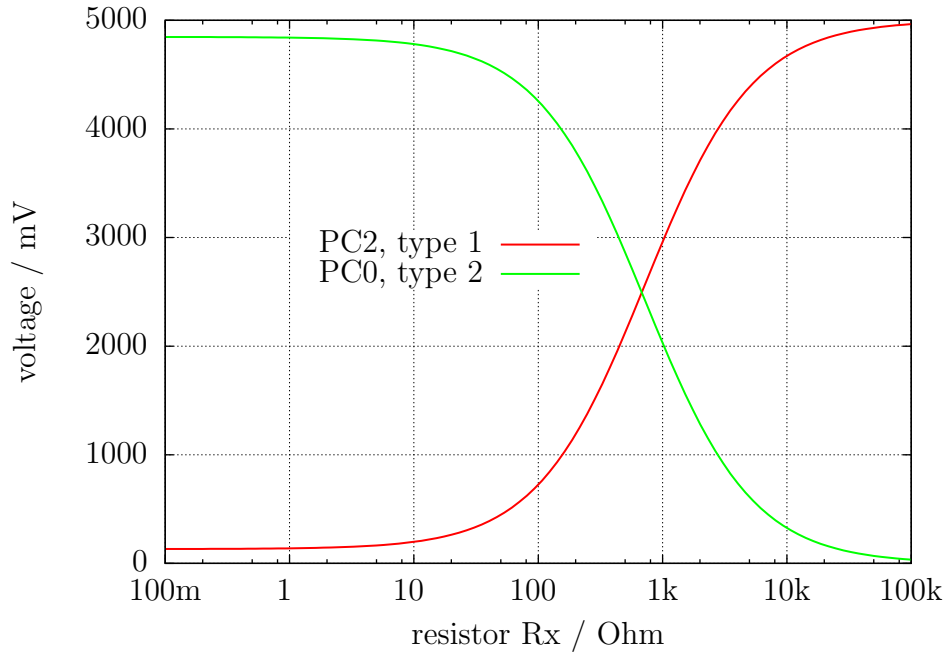
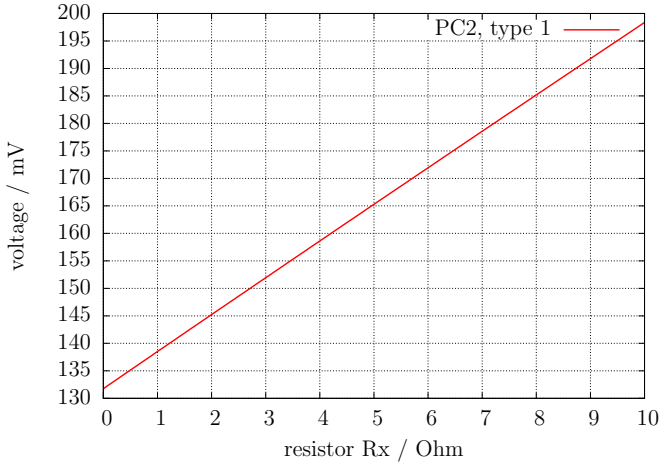


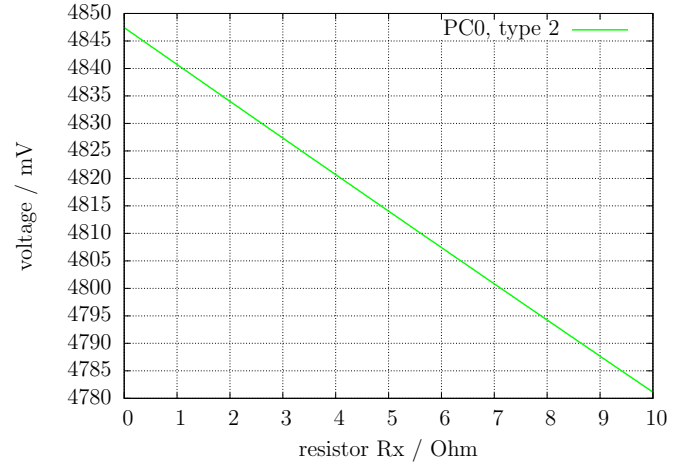
Figure 5.10: Voltages of type 1 and type 2 measurements with 680Ω

The graph of measurement type 1 is shown in figure 5.11a with zoomed scale for the lower resistor range. You can see, that you need a better ADC resolution than the standard 4.9mV resolution at the 5V ADC reference, to get the right resistor value from measured voltage below 2Ω . There are only three ADC steps from 0Ω to 2Ω . The range switching with the AUTOSCALE_ADC option can help in this case. The same zoomed range of measurement type 2 shows the figure 5.11b. Unfortunately we can not use the higher ADC resolution for measurement type 2 in this range, because the voltage is too high and our ATmega have no differential ADC input. Measurements with the 680Ω resistors are taken for building the result of measurements up to $20\text{k}\Omega$ (Voltage of measurement type 2 will be below 169mV).

For higher resistor values the measurements with the $470\text{k}\Omega$ resistors are used. The mean value of both measurements is taken as displayed resistor value, if all tests attests, that it is no other type of part. If the AUTOSCALE_ADC function is selected and one of the voltages of the both measurement types is below 0.98V , a weighted average is build with factor four for this value. The other value is weighted with factor one. This is done to respect the factor four better resolution of this measurement. Factor four is only taken for ATmega168 and ATmega328 processors, for the ATmega8 two is taken as weighting factor if voltage is below 0.98V , because the reference voltage for the ADC is here 2.54V instead of 1.1V . If the ATmega has more than 8KByte flash memory, the voltage measurement at the resistors will be delayed until no more changes are detected or the time limit is reached. With this method big capacitors are no more detected as resistors by mistake and the DC resistance of big inductors will be measured correctly.



(a) Type 1 measurement



(b) Type 2 measurement

Figure 5.11: Cut-out of theoretical Voltage from 0Ω to 10Ω

5.2.2 Resistor Measurement with $470\text{ k}\Omega$ resistors

The next figures 5.12 and 5.13 shows the same measurement procedure for the measurement with the precision $470\text{ k}\Omega$ resistors. Because the $470\text{ k}\Omega$ is very big in relation to the port resistor values 22Ω and 19Ω , the port resistor values are ignored for the computing of the resistor value R_x .

For both measurement types with the $470\text{ k}\Omega$ resistors only one Voltage is measured, because the current is so low, that no voltage difference at the internal port resistors of the ATmega can be measured (as expected). The theoretical voltage gradient is shown in figure 5.14 where the resistor values are again shown in logarithmic scale. The theoretical gradient in this diagram ends at $100\text{ M}\Omega$, but the resulting value of the Tester is limited to $60\text{ M}\Omega$, otherwise the Tester assumes that no resistor is connected. The weighted average of both measurement types is taken as result with the same rules described for the measurements with the 680Ω resistors. For all ATmega processors I had found, that the measured results with the $470\text{ k}\Omega$ resistors are more exactly, if a constant offset of 350Ω will be added. This offset can be adjusted with the `RH-OFFSET` define in the `config.h` file.

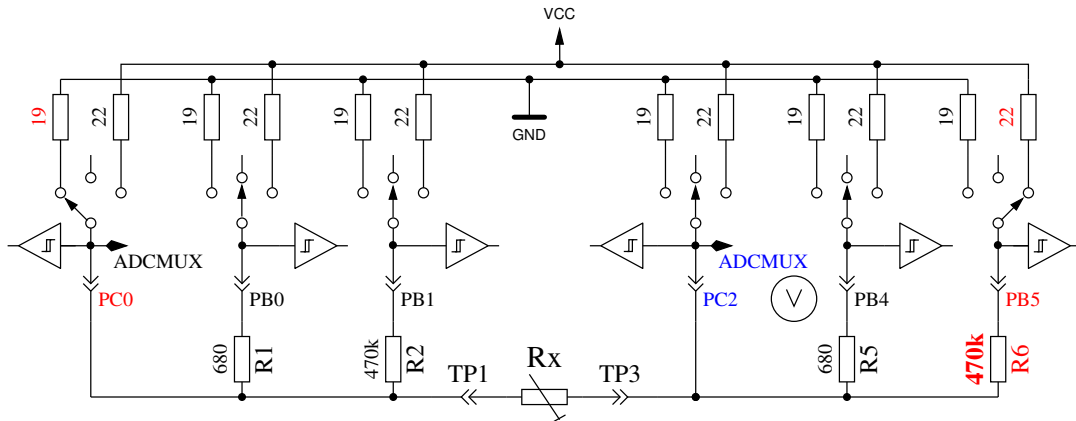


Figure 5.12: Measurement type 3 with $470\text{ k}\Omega$

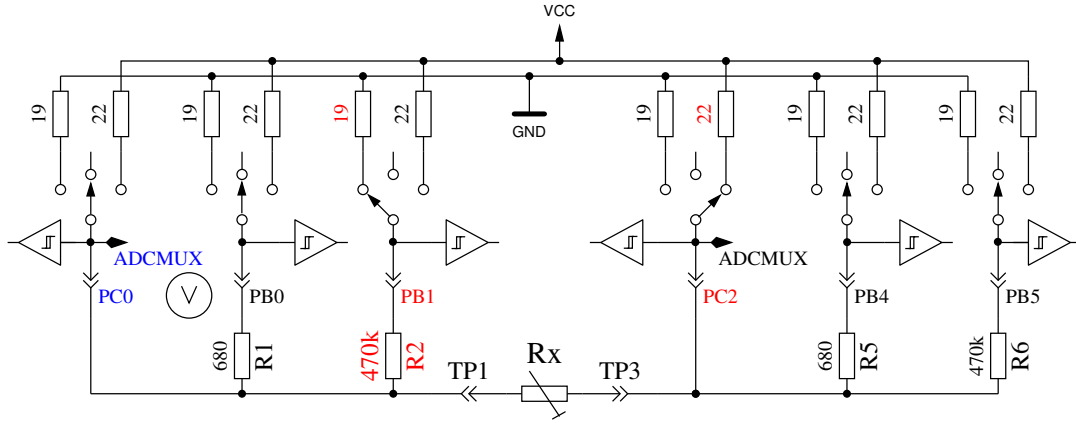


Figure 5.13: Measurement type 4 with 470kΩ

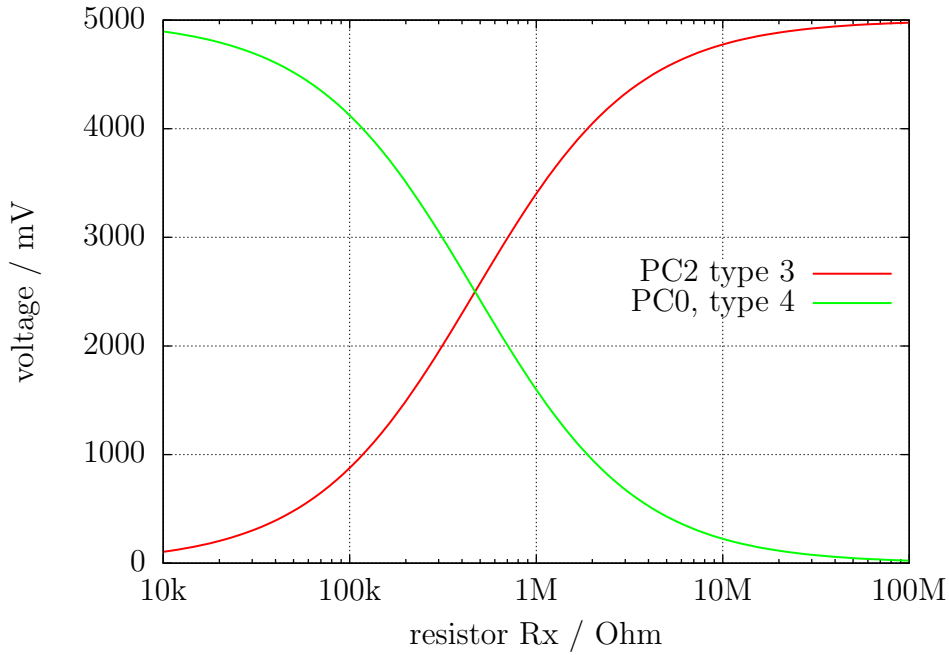


Figure 5.14: Voltages of type 3 and type 4 measurements with 470kΩ

5.2.3 Results of the resistor measurements

Figure 5.15 shows the relative errors of the resistor measurements with three ATmega8 microcontrollers. Additionally some results with the original software of Markus F. with one ATmega8 are shown as "Mega8orig" in this figure. More measurements results with ATmega8A and ATmega8L are shown in figure 5.16a and 5.16b. Figure 5.17 shows the same measurements with a ATmega168 microcontroller. Mega168 are the results without the AUTOSCALE_ADC option, Mega168as are the same measurements with the AUTOSCALE_ADC option. With the ATmega168 microcontroller it seems to be possible, that measurements of resistors in the range from 20Ω to 20MΩ can be measured with a tolerance of $\pm 1\%$. For Measurements below 100Ω you should keep in mind, that any measurement probe with wire have a resistance too. It is better to connect the resistor directly to the terminal pins. If this is not possible, subtract the resistance value of the shortened probe. For example, if your Resistor have a printed value of 30Ω, your tester shows a value of 30.6Ω and the two probes shortened have a value of 0.5Ω, then your resistor has been measured with 30.1Ω. Below a resistance value of 10Ω one resolution step results to a error of more than 1%!

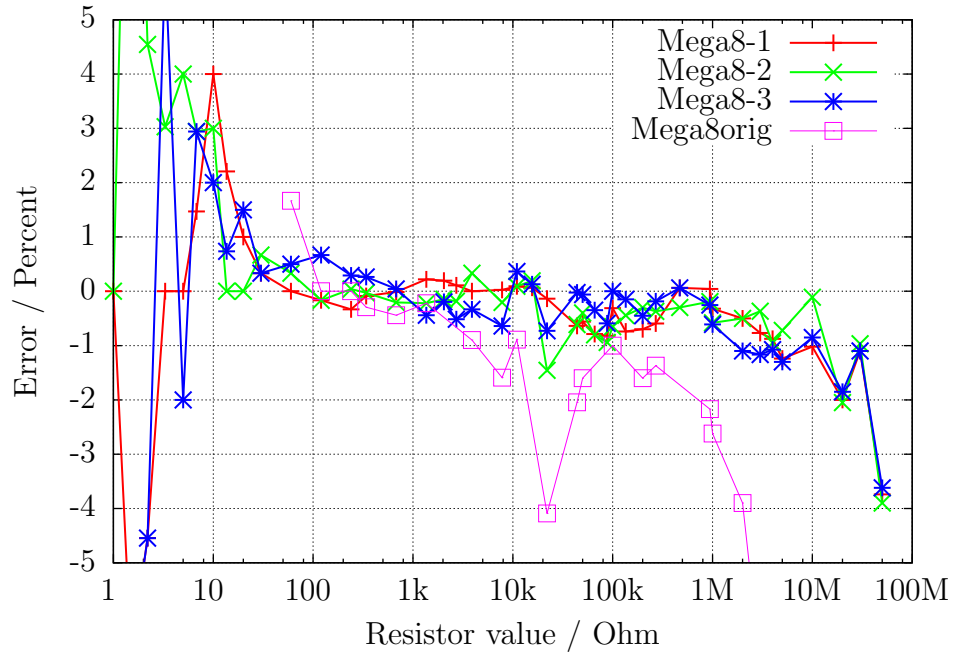
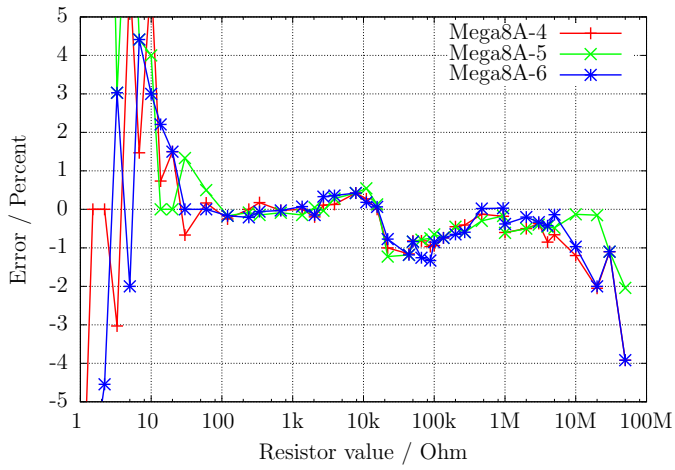
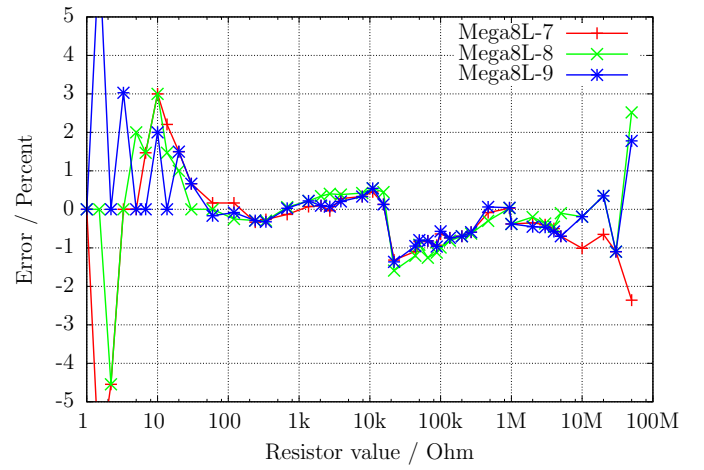


Figure 5.15: Relative error for resistor measurements with ATmega8



(a) with three ATmega8A



(b) with three ATmega8L

Figure 5.16: Relative error for resistor measurements

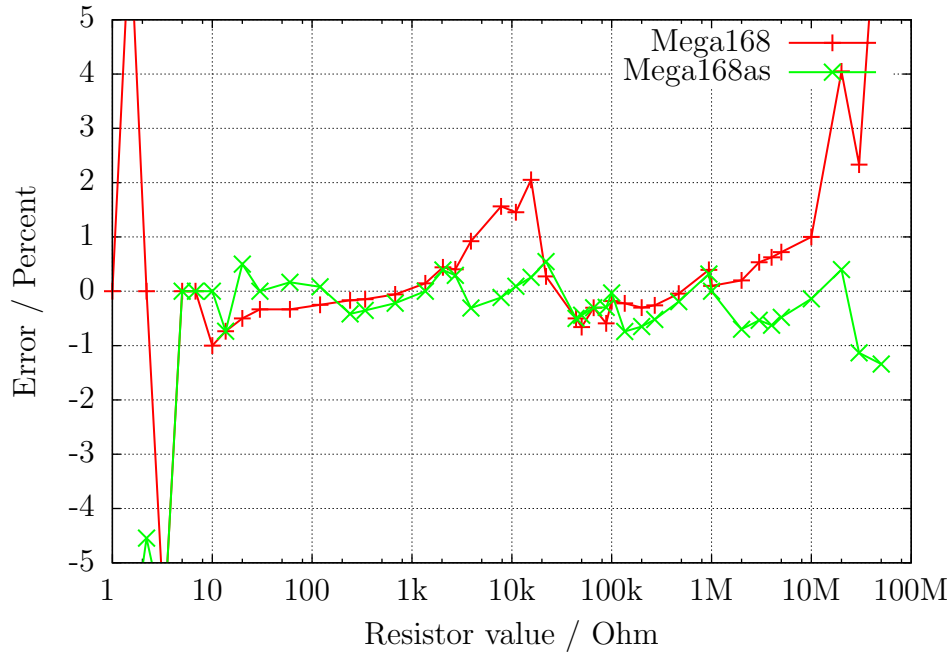
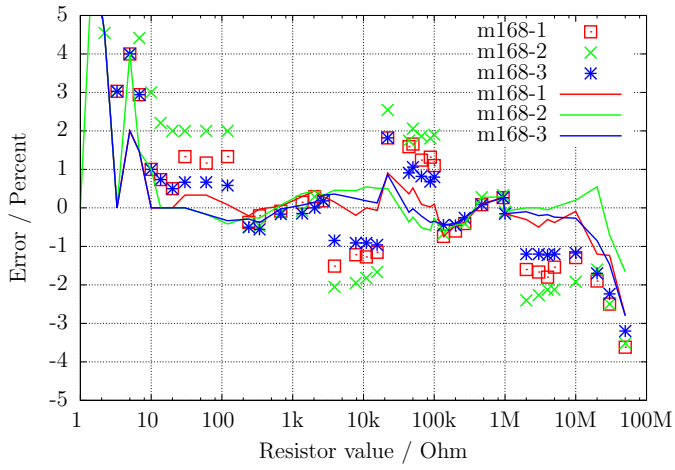
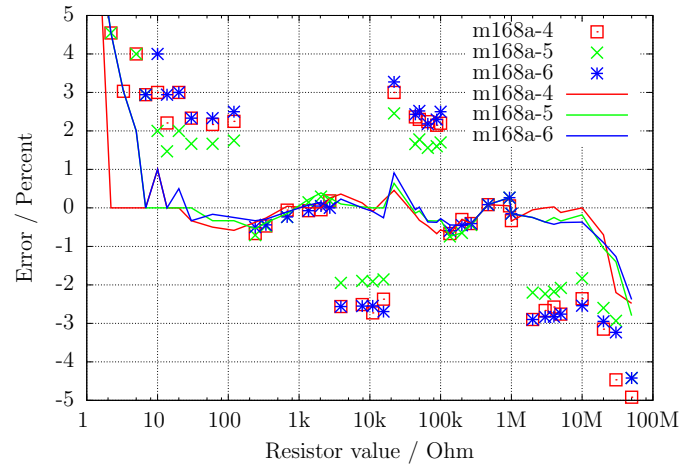


Figure 5.17: Relative error for resistor measurements with ATmega168

The figure 5.18a shows the measurement errors of three ATmega168 processors before calibration as points, after the calibration as line. The equivalent measurement errors of three ATmega168A processors are shown in figure 5.18b and the measurement errors of three ATmega168P processors are shown in figure 5.19 . The measurement errors of three ATmega328 processors are shown in figure 5.20a and 5.20b. After the automatic calibration the relative measurement errors of resistors between $10\ \Omega - 20M\Omega$ usually are in the limit $\pm 1\%$. Only one measurement of a $22k\Omega$ resistor with the ATmega328P-13 shows a higher error. Before the calibration errors of some processors are found with $\pm 3\%$. This will be caused by the AUTOSCALE_ADC switching of the ADC reference. The direct compare of a capacitor voltage below 1 V, once measured with the VCC reference and another once measured with the internal reference, can adjust this error. With this measurement condition the voltage is measured with the same multiplexor channel and the internal bandgap reference is connected to the AREF pin of the ATmega. Unfortunately the direct measurement of the bandgap reference with the special multiplexor channel results to this offset, which can be manually adjusted with the REF_R_KORR option or automatically with the AUTO_CAL option of the selftest. With the AUTO_CAL option the REF_R_KORR value is a additional offset to the automatic find out value!



(a) with three ATmega168



(b) with three ATmega168A

Figure 5.18: Relative error for resistor measurements

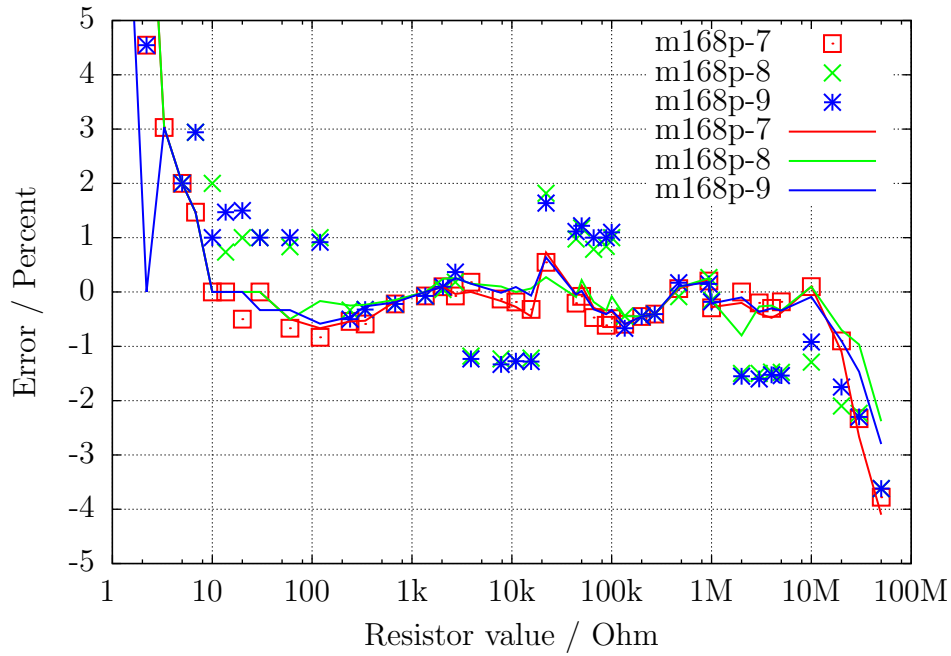
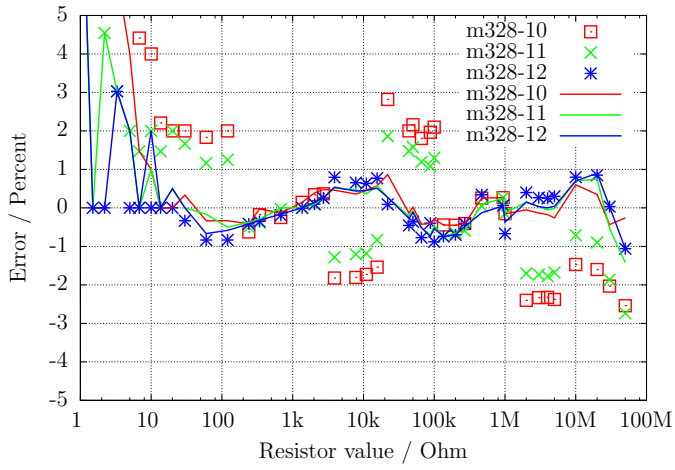
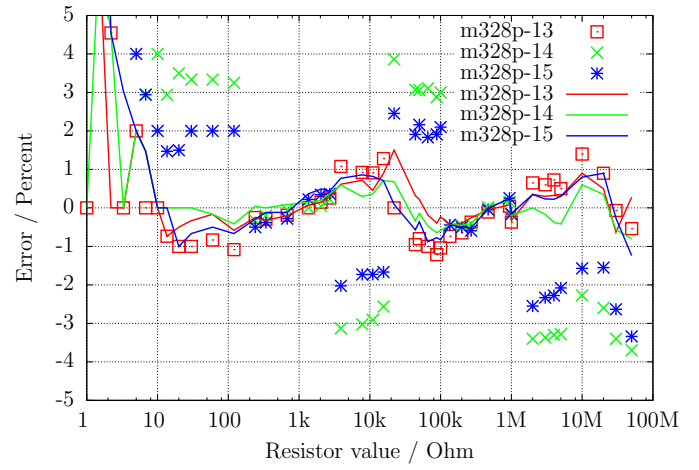


Figure 5.19: Relative error for resistor measurements with three ATmega168P



(a) with three ATmega328



(b) with three ATmega328P

Figure 5.20: Relative error for resistor measurements

5.3 Measurement of Capacitors

The measurement of capacitor values are done as separate task by measurement of load time after all other measurements. The original software of Markus F. did this with a program loop, which reads the corresponding digital input pin until a switch occurred and count the loop cycles. This has the handicap, that the resolution of time measurement is limited by the time consumption of one loop cycle. This usually was done in all six combinations for all three probe pins. The actual software uses two different ways to get the load time in only three combinations for the three probe pins. The positive side is now always the higher probe number. Only if capacity is measured parallel with a diode, the polarity can be in the other order.

5.3.1 Discharging of Capacitors

You should always discharge the capacitor before connecting it to the tester. The tester additionally discharge the capacitor before any measurement. If the voltage is below 1300mV, the capacitor is shortened by the output pins of the connected ADC port (Port C). I believe that this is legal because every output port has a built in resistance of about 20Ω . The data sheet Figure 149 (page 258) [2] shows voltage drop of output pins up to 2V. Of course I can not guaranty, that no damage can occur. I have tested the function with big capacitors of more than $15mF$ many times and I have never noticed any problem. The current should be below the specified limit of 40mA and is reduced fast by discharging. Of course damage can occur if you do not discharge a (high voltage) capacitor before connecting it to your tester.

5.3.2 Measurement of big Capacitors

One side of the capacitor is connected to GND. The other side of the capacitor is connected with the 680Ω resistor to VCC for a period of 10ms. Afterwards this probe pin is switched to Input (High Impedance). After this 10 ms current pulse the voltage of the capacitor is measured without any current. If the voltage has not reached a minimal value of 300mV, the load pulse is repeated up to 499 times. If after 127 pulses a minimum voltage of 75mV is not reached (about 2s), further load is stopped, because never the 300mV can be reached with the remaining load pulses. Figure 5.21 shows the three phases of measuring the capacity value of a capacitor. The value of the capacity is then computed with the count of load pulses and the reached load voltage from a table. The table contains the factors to get the capacity in nF units from load time and the reached voltage with a spacing of 25mV. Interim value of voltage will be interpolated.

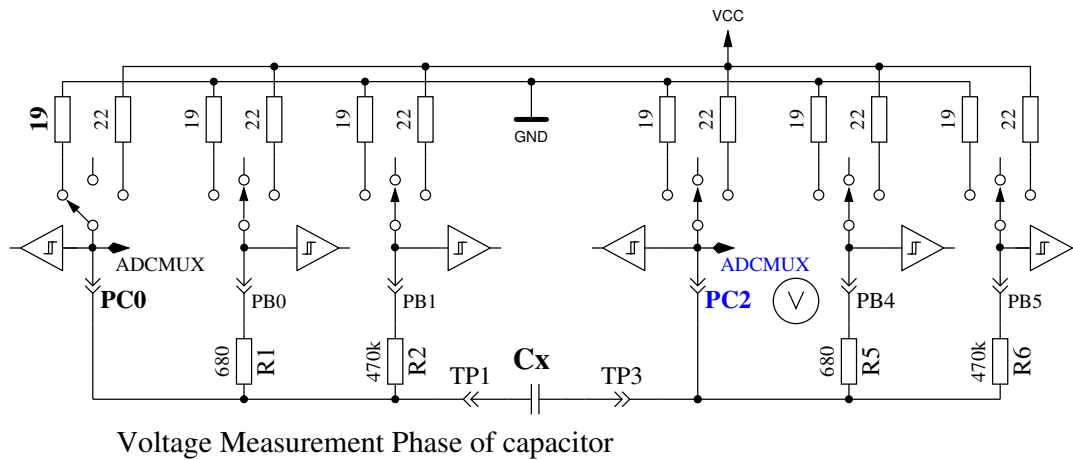
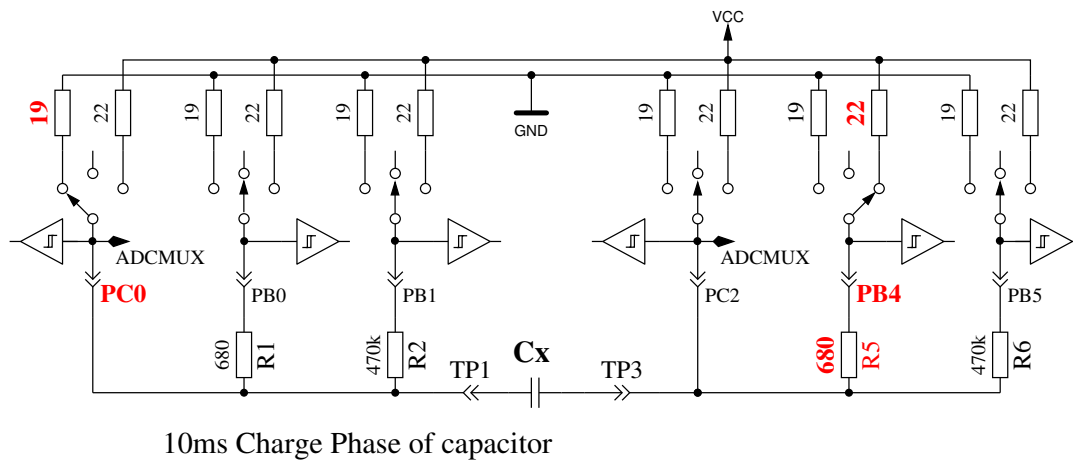
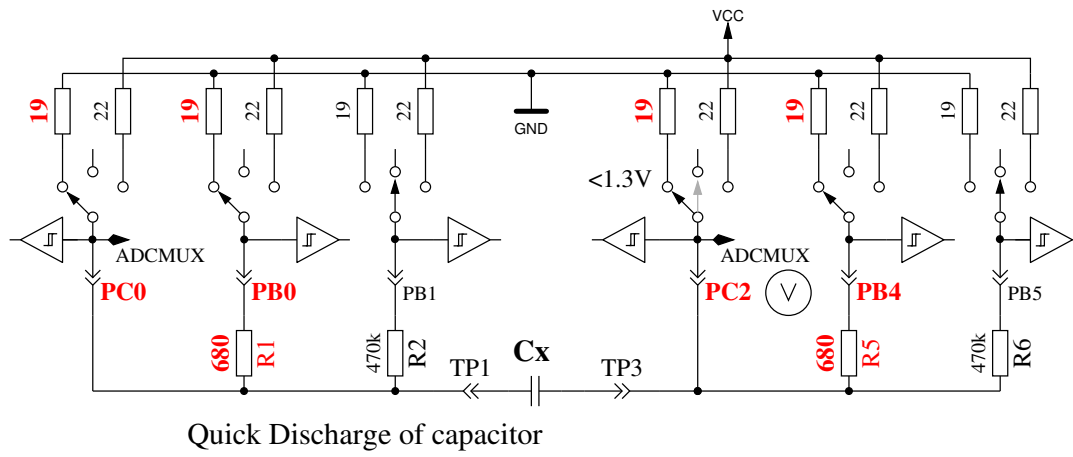
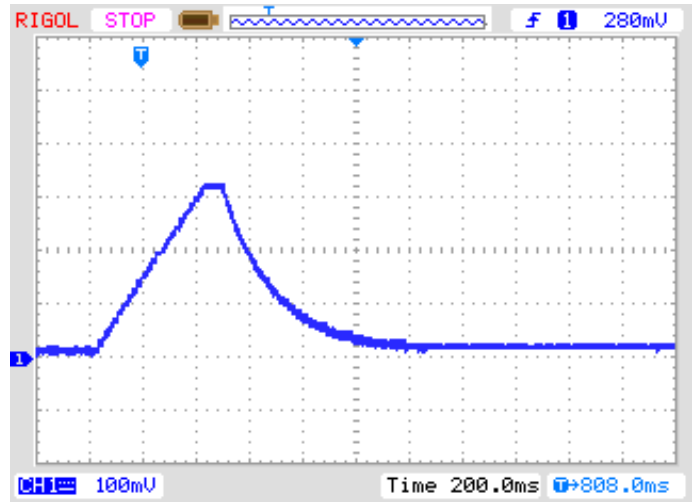


Figure 5.21: discharge a capacitor and load with 10ms load pulses until voltage reach a value of 300mV

As a result of the low load voltage, the measurement is much faster than the initial software version, because this advantage works also on discharging. So bigger capacitors can be measured. Furthermore a diode, which is parallel connected to the capacitor dont disturb the measurement in most cases, because the flux voltage of most diodes is not reached. Figure 5.22a shows the charge and discharge for a $229\mu F$ capacitor. The flat top of diagram from load end to discharge begin is caused by the measuring and computing time of the ATmega. Figure 5.22b shows the same measurement for a $5mF$ capacitor, notice how the time for measurement is grown to about 1.5 seconds inclusive the discharge. The last example shows the capacity measuring of a $15mF$ capacitor in Figure 5.23



(a) $229\mu F$ Capacitor



(b) $5mF$ Capacitor

Figure 5.22: Charge and discharge of big Capacitors for measuring

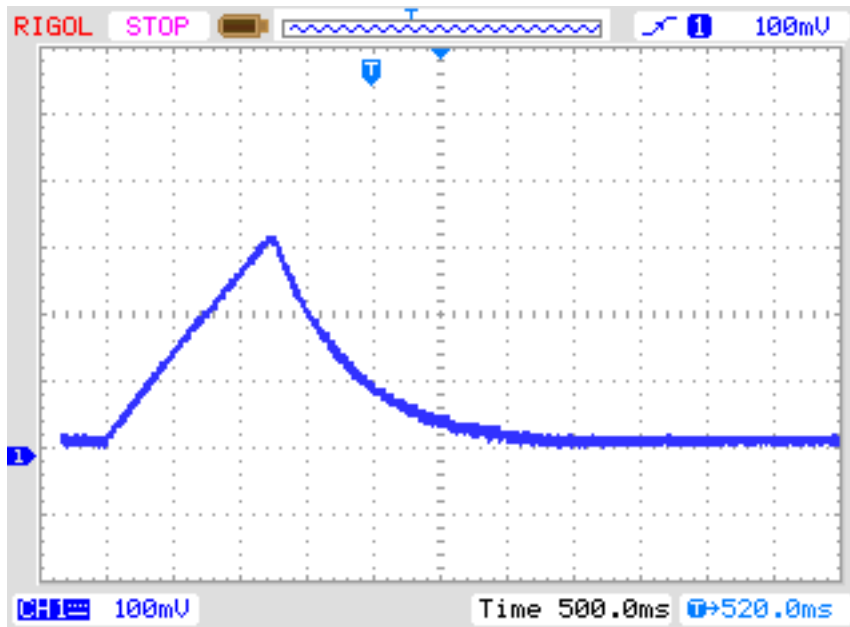


Figure 5.23: Charge and discharge of a $15mF$ Capacitor for measuring

After this capacity measurement the self-discharge of the capacitor will be checked by waiting a proportional period the loading has taken and reading the load voltage again. The measured capacity value is corrected due to this voltage drop. A test with a parallel connection of a $68\mu F$ capacitor and a $2.2k\Omega$ resistor shows the effectivity of this method. The measured capacity value without the resistor is $66.5\mu F$, with the parallel $2.2k\Omega$ resistor results to a capacity value of $66.3\mu F$. For comparison here are the results measured with a Peaktech 3315 multimeter: Without the resistor a capacity value of $68.2\mu F$ is measured, with the parallel $2.2k\Omega$ resistor a value of $192\mu F$ is measured with the multimeter.

5.3.3 Measurement of small Capacitors

If the first 10 ms load pulse has overloaded the capacitor, another technique of measurement is used. The ATmega processor has a build in 16-Bit counter, which can operate at the full clock rate (1MHz

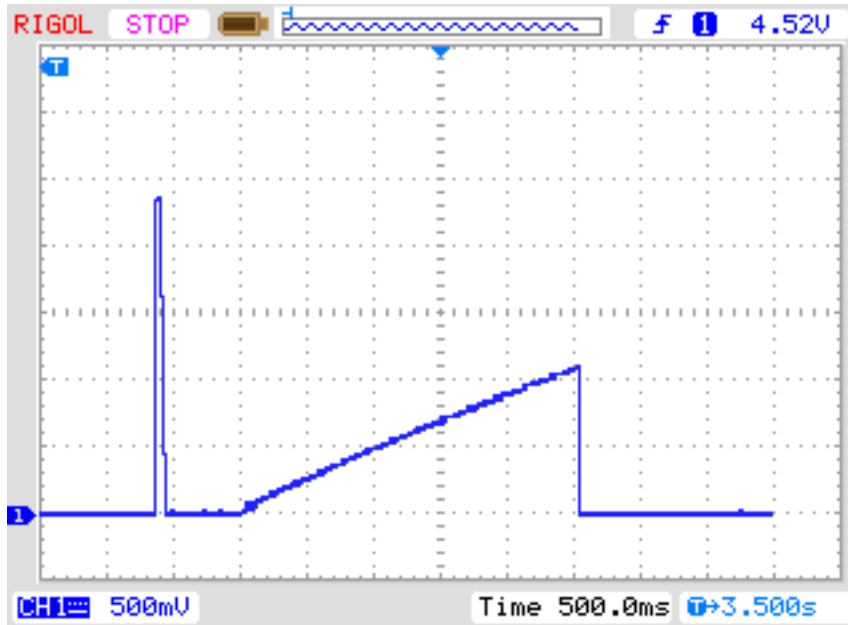


Figure 5.25: Charge and discharge of a $22\mu F$ Capacitor for measuring

In principle this technique of measurement can also be done with the 680Ω resistor, but because the ADC can't be used if the comparator is working, I have no chance to monitor the load voltage until the comparator is stopped. If a undetected diode is parallel connected with the capacitor, the load current of the capacitor can be absorbed by the diode (threshold voltage) and the band-gap voltage will never be reached. The method taken in actual software for big capacitors in section 5.3.2 avoids this conceptual bug.

5.3.4 Measurement of the Equivalent Series Resistance ESR

If the measured capacitor has a capacity of more than about $2\mu F$, the tester will try to measure the series resistance too. The series resistance ESR [8] is a good indicator for the aging of electrolytical capacitors for example. The figure 5.26 shows a equivalent circuit of a capacitor. The resistor R_p represents the leakage resistance of the capacitor, ESL the equivalent series inductivity and the resistance ESR represents the equivalent series resistance.

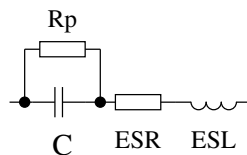


Figure 5.26: Equivalent circuit of a capacitor

Strictly speaking the ESR of a capacitor depends on the operating frequency and temperature. Usually the value measured with sine wave-form signal of $100kHz$ is denoted in the data sheets. This measurement can not be done with the ATmega without external equipment. With the subsequent written method a measurement frequency will be below 680 Hz with nearly rectangular signal. To get the value of the equivalent series resistance, the voltage of both connections will be measured during loading in one direction with the ADC internal reference voltage (1.1 V). After the measurement the load current will be switched off and the voltage of the capacitor is measured again without the current. If this voltage is below 3 mV, the sequence of measurement is repeated. The figure 5.27 shows the corresponding circuits.

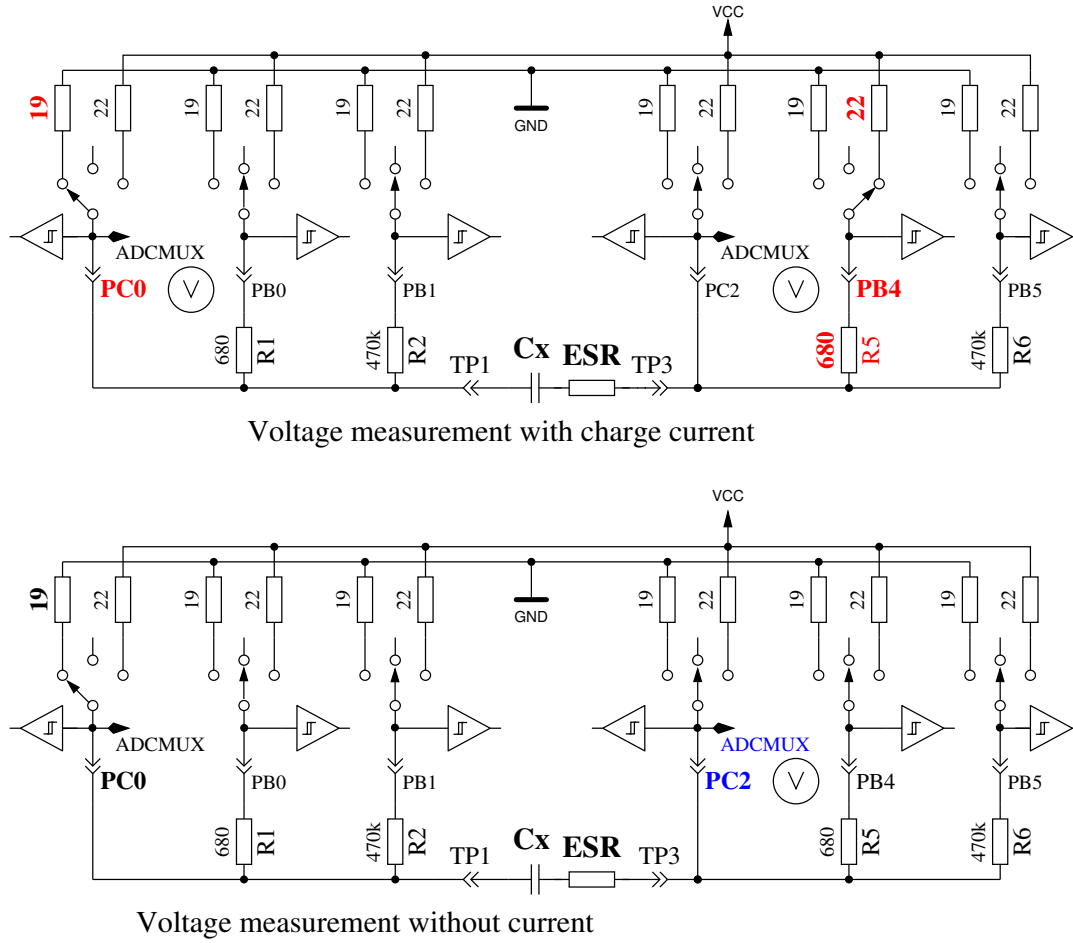


Figure 5.27: Circuit of the ESR measurements of a capacitor

The difference of capacitor voltages with and without current is proportional to the internal resistance of the capacitor. The expected voltage of this difference is so low, that one measurement can not result to a feasible result. Therefore after this the current will be switched to the opposite direction and the same measurement will be repeated. The whole measurement sequence will be done 128 times and the results of the voltage measurements will be added. So we have three sums of voltages, the voltage U_{lp} at the low side of the capacitor with current, the voltage U_{hp} at the high side of the capacitor with current and the voltage U_c of the high side of the capacitor without current. The sum of voltages at the low side of the capacitor represents the potential drop with the mean load current at the port output resistance R_{port} . The voltage difference of the high side and the low side of the capacitor represents the voltage of the capacitor with load current $U_{diff} = U_{hp} - U_{lp}$. The difference $U_{esr} = U_{diff} - U_c$ should represent the voltage drop at the internal resistance of the capacitor with mean load current. We will get the resistance value with the relation of this voltage U_{esr} to the voltage U_{lp} , scaled with the known resistance value of the port output R_{port} . The scale factor is selected to get a resistance resolution of 0.01Ω : $R_{esr} = \frac{U_{esr} \cdot 10 \cdot R_{port}}{U_{lp}}$ The accuracy of the ESR measurement is not very high by different reasons:

1. The voltage measurement at both pins of the capacitor can not be done at the same time, the only way is to do it in sequence. In the interim time between both measurements the load current has changed due to the charge of capacitor. The program tries to compensate this fact with a capacity dependent correction of the low side voltage.
2. The ADC takes the measurement voltage after 1.5 clock ticks after the start of conversion. The conversion begins with the rising edge of the ADC-clock, if the start bit is set. If the charge

current will be switched off to early, the ADC takes the wrong voltage for the measurement with current. If the charge current will be switched off to late, the capacitor will take more electric charge, than that of the corresponding measurement with load current. This will cause a too high voltage of the measurement without current. But it is difficult to switch off the current at the right time by software. The added voltage sum of the measurements without current is reduced by 2 % to compensate the overloading.

3. The port output resistance is used as a reference value by this measurement method, but this resistance value is not exactly known too.
4. The resolution of the ADC is not sufficient to get a resolution of 0.01Ω . To get the best available resolution of ADC, the internal reference (1.1 V) is used for all measurements. The resolution deficit will be attenuated by accumulating a big number of single measurements too.
5. The switching of ports can not be exactly synchronized to the ADC clock with polling of conversion done.

Anyway the results seems to be practical, as shown with the following figure 5.28. The ESR values of the same part measured with the Transistortester vary more than the values measured with the LCR meter. All ESR results from the LCR meter are measured with a frequency of 1 kHz. You must respect the quality of all connection parts. The used cable connections can cause a higher measured resistance value. The plug connectors can also result a higher resistance value. The LCR meter has the advantage of the used Kelvin terminals.

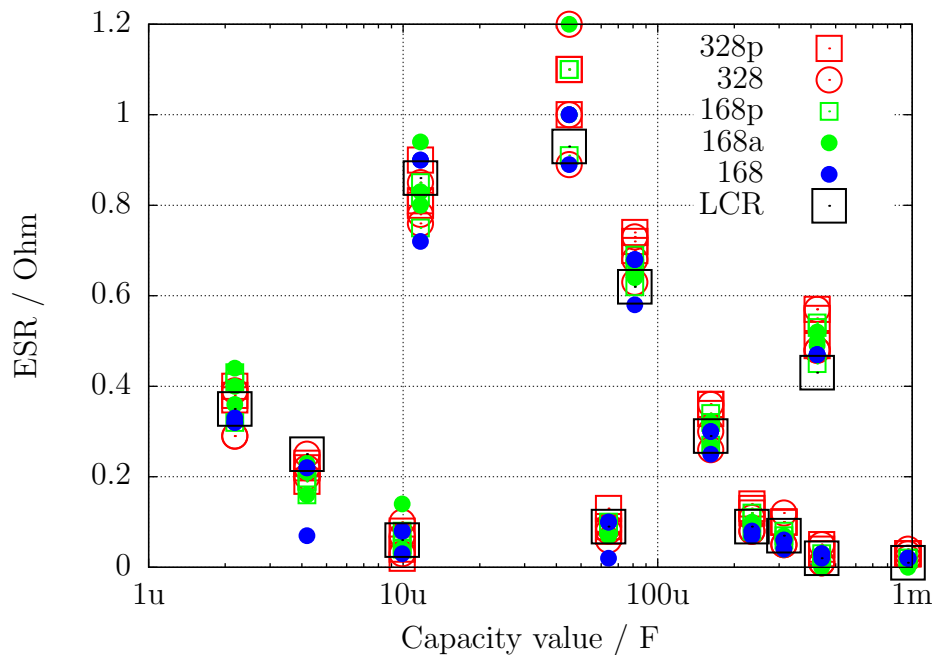


Figure 5.28: ESR measurement results of 15 different ATmega

5.3.5 Results of Capacitor measurement

The results of my capacity measurements are shown in figure 5.29 for three ATmega8 processors. Additionally some values of original software are shown with a correction factor of 0.88 (-12%). Other measurement results of different ATmega8 versions are shown in figure 5.30a and 5.30b. The results of the measurement of the same capacitors for a ATmega168 is shown in figure 5.31. The base for

the error computing are the measurement results of a PeakTech 2170 RCL-meter, not the printed value of the parts. A part of the relative high measurement difference is caused by the too high measurement frequency of the RCL-meter for big electrolytical capacitors. On the other side the bad quality factor of the electrolytical capacitors may cause another percentage.

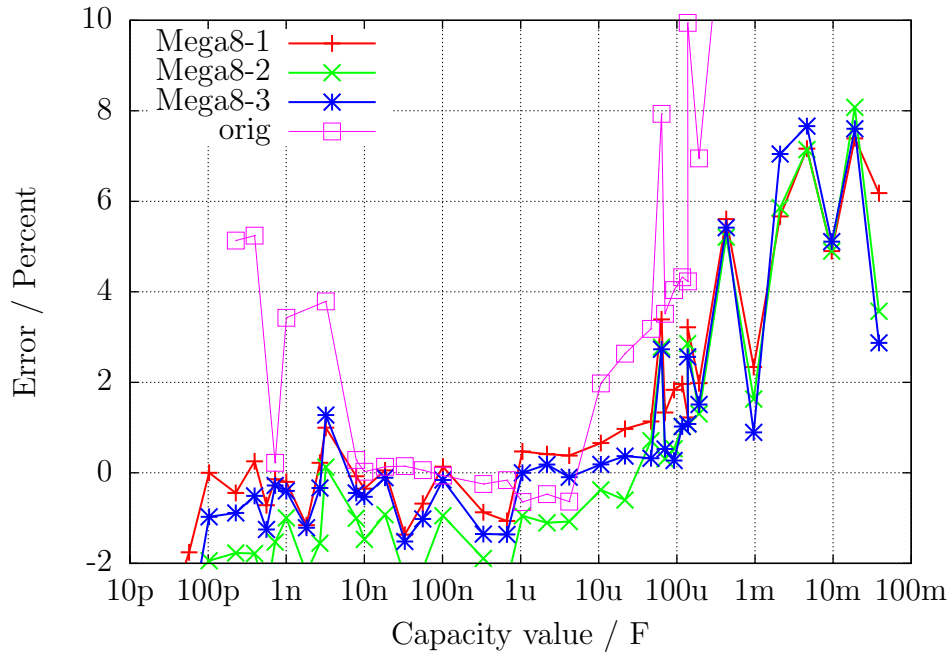
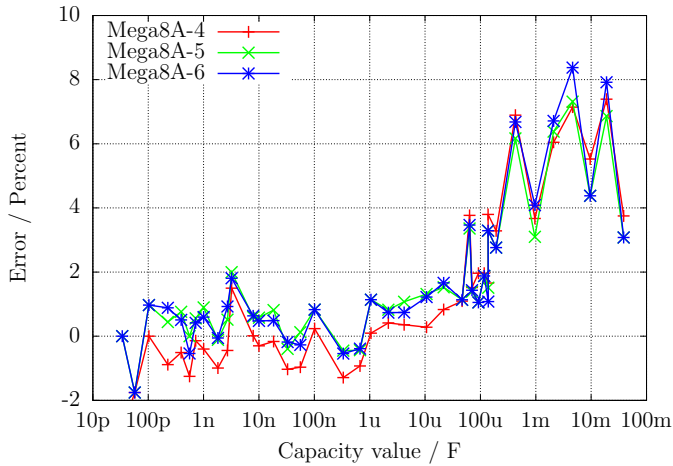
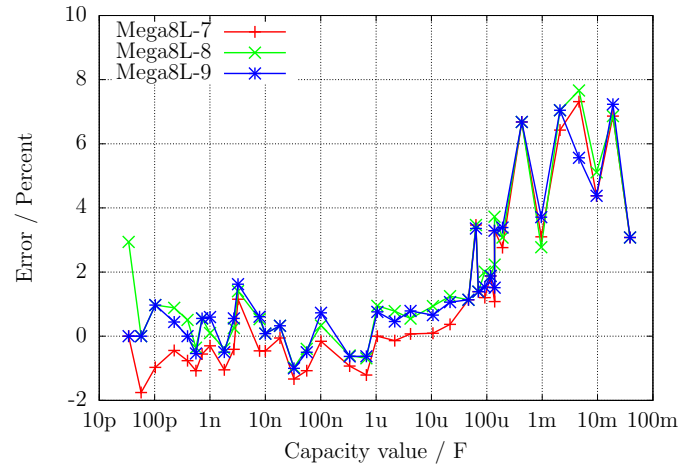


Figure 5.29: Error in % for capacitor measurements with ATmega8



(a) with three ATmega8A



(b) with three ATmega8L

Figure 5.30: Relative error of capacitor measurement

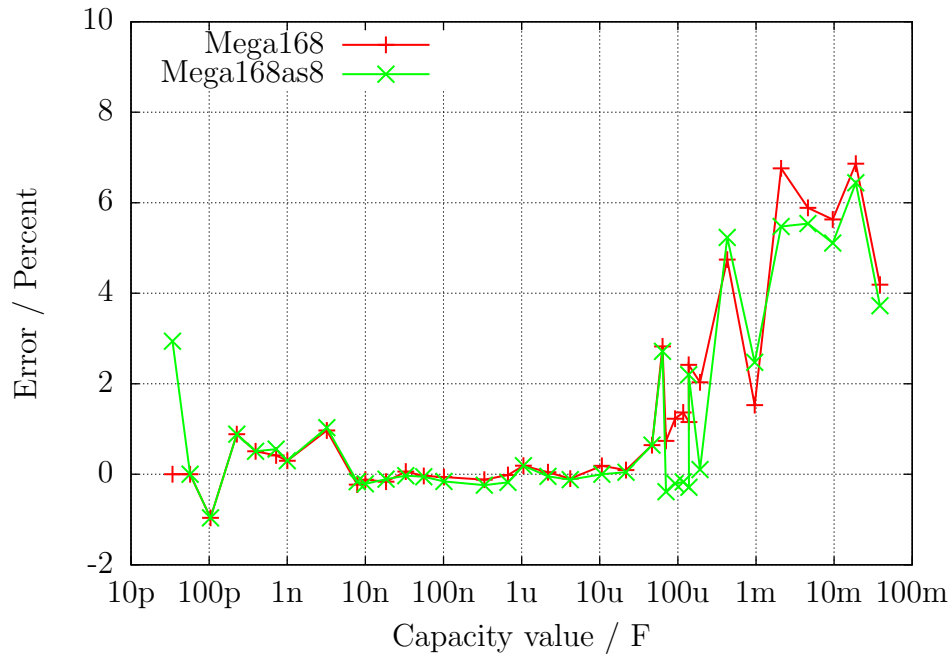


Figure 5.31: Error in % for capacitor measurements with ATmega168

Figure 5.32 illustrates, how difficult is it to choose the right base for the capacity measurement. All measurement results are compared with the best estimated value of the capacitors. The gradient „Multimeter” shows the differences of the Peaktech 3315 Multimeter results. The next gradient „LCR” shows the differences of the Peaktech 2170 LCR-Meter results, which is taken from best frequency approach. To compare this results to the results of a ATmega168 equipped Transistor-Tester the gradient „ATmega168as” is also shown. I beleave, that this errors are not real measurement errors of the particular equipment, because my best estimated value are also not the real capacity value of the capacitors.

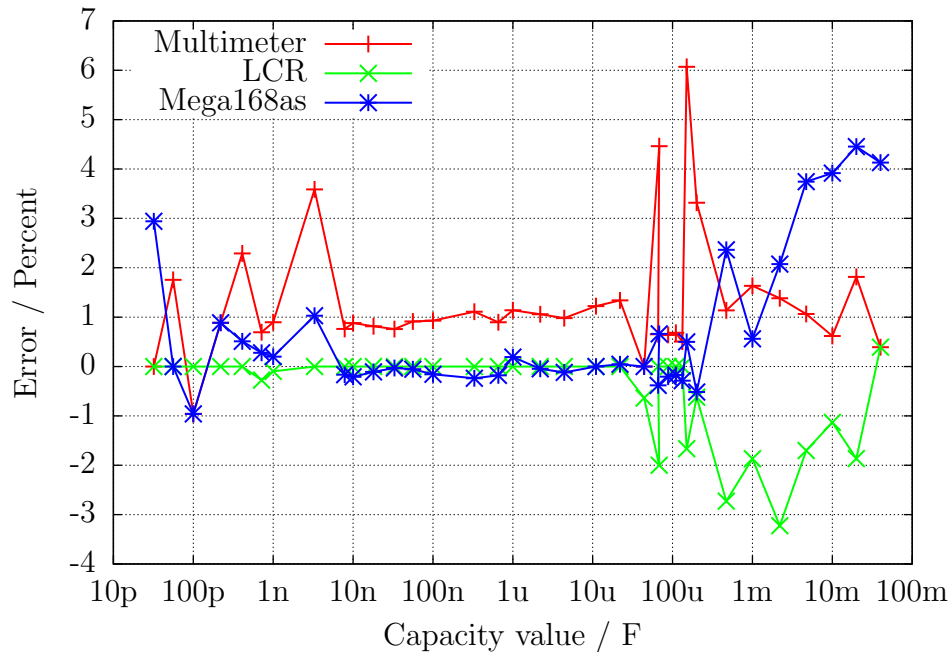


Figure 5.32: Comparison of capacity measurement results of Multimeter, LCR-meter and ATmega168

The differences of measurements of three different ATmega168 processors are shown in figure 5.33a

. In this case the results of the LCR meter is taken as base of comparison. The same results of three different ATmega168A processors are shown in figure 5.33b and three different ATmega168PA processors are shown in figure 5.34. The results of three ATmega328 are additionally shown in figure 5.35a and the results from three ATmega328P are shown in figure 5.35b. At this only the zero value of the capacity measurement of 39pF is respected, all other facility to correct the results are not used. This zero value includes the 2-3pF, which are caused by the 12 cm long cable with the clips. The board layout can cause a different zero value, I have fixed this zero value with the board "DG2BRS V 5.2.1".

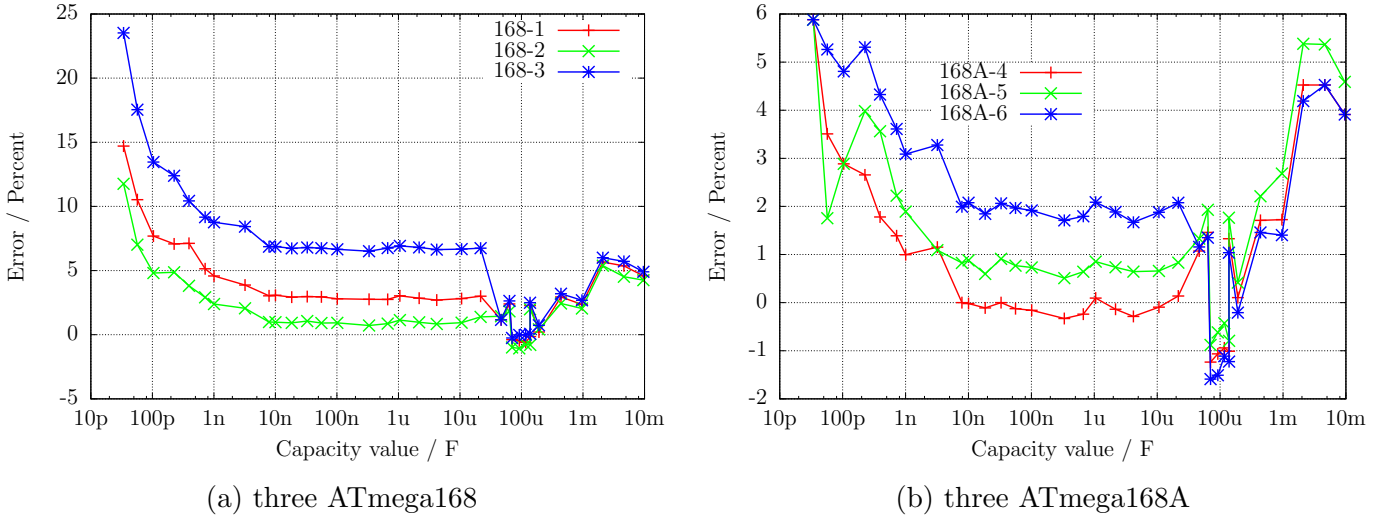


Figure 5.33: capacity measurement error, not calibrated

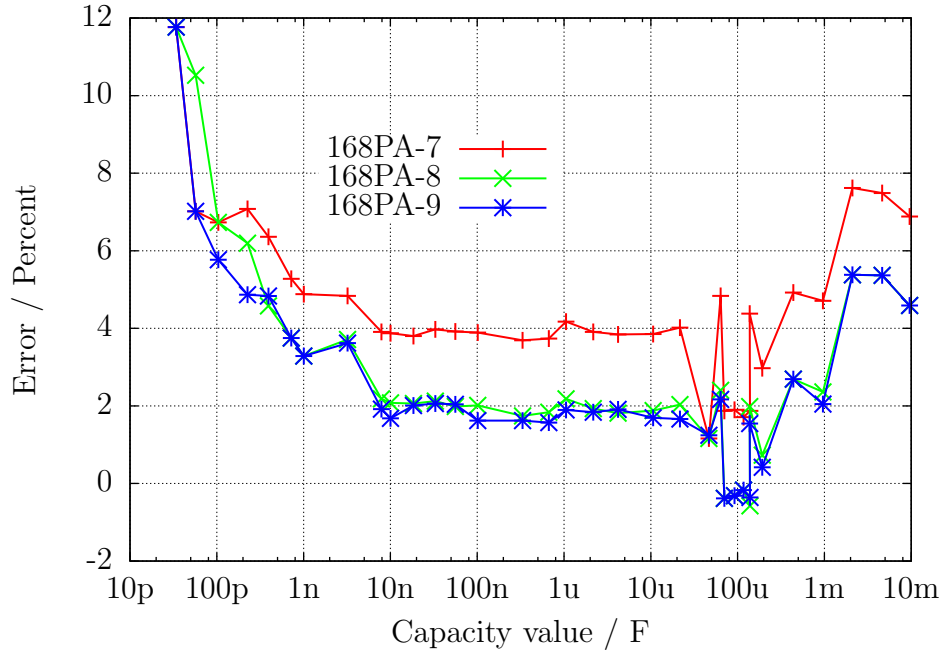
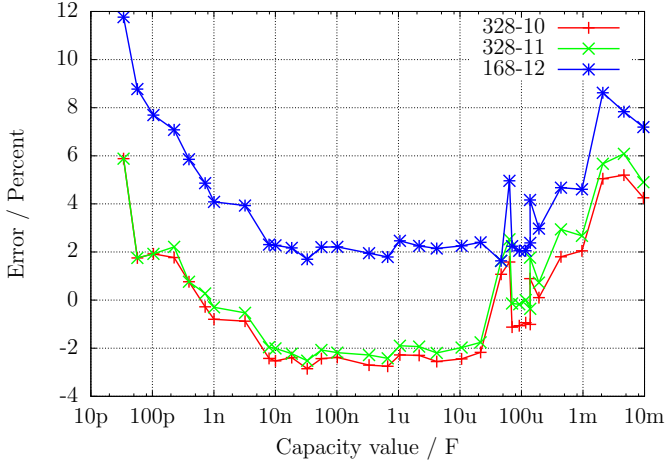
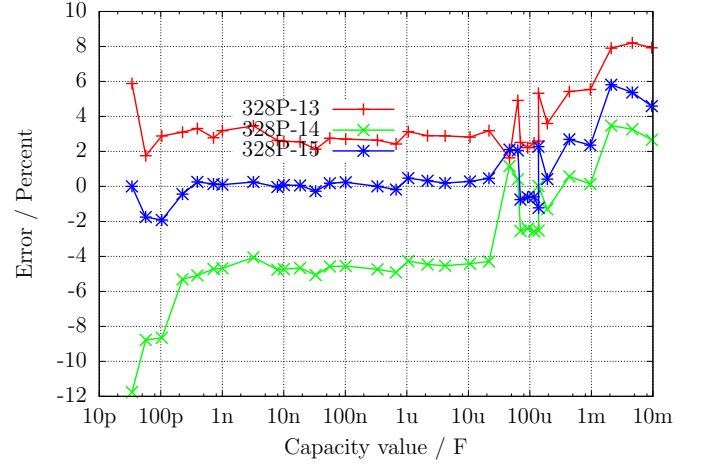


Figure 5.34: capacity measurement error of three ATmega168PA, not calibrated



(a) three ATmega328



(b) three ATmega328P

Figure 5.35: capacity measurement error, not calibrated

To get the best accuracy you must adapt the software to the individual characteristic of your ATmega exemplar. For this you can set a correction voltage REF_C_KORR for the comparator, which will be used for measurement of little capacity values. A correction of 1 mV will reduce the measurement results to 0.11 % . For big capacity values you can specify with the per mill value C_H_KORR, how much your capacity values are measured too big. Because the capacitors with big values are most electrolytic capacitors with worse quality factor, the measurement of the capacity value is difficult. So it is also extra difficult to get the difference to the real value of a capacitor.

Especially with the ATmega168 processors I have noticed a anomaly of measurement results of little capacity values, which depend on the slew rate of the voltage during loading of the capacitor. Figure 5.36 shows the error of the capacity measurement when only the zero value is respected (168-3-A), with correction factor for little capacitors REF_C_KORR=66 as well as the correction factor for big capacitors C_H_KORR=5 (168-3-B), plus additional as gradient 168-3-C with a model of the slew rate dependency of little capacitor measurements ($COMP_SLEW1=4000$ und $COMP_SLEW2=220$). Also the self-discharge of big capacitors is respected with gradient 168-3-C. The component with the slew rate dependent value is computed with $\frac{COMP_SLEW1}{cval+COMP_SLEW2} - \frac{COMP_SLEW1}{COMP_SLEW2}$, where cval is the measured capacity value with pF units.

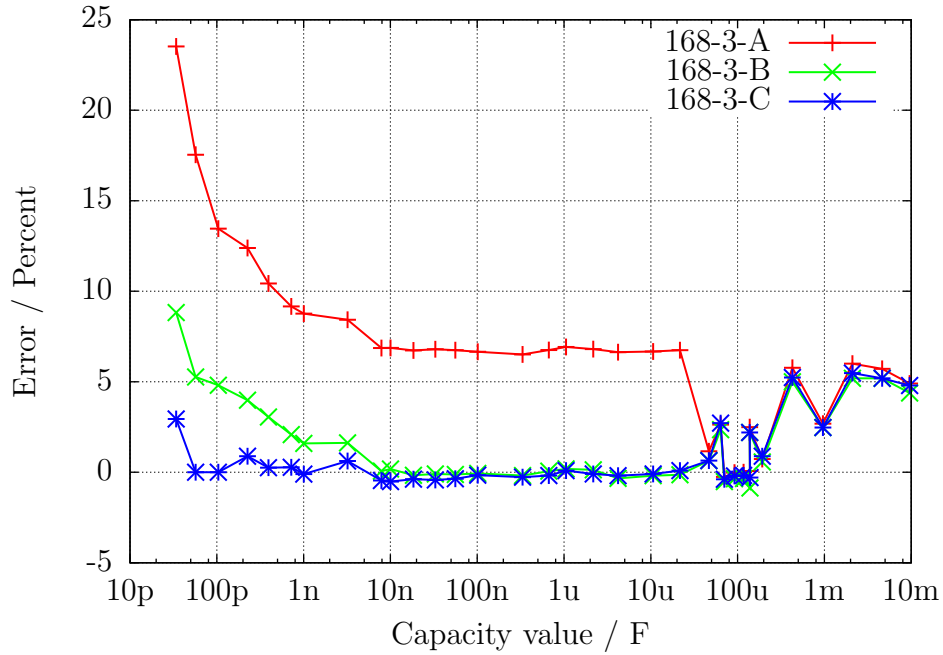


Figure 5.36: Improvement of the capacitor measurement of one ATmega168

5.3.6 Automatic calibration of the capacitor measurement

The automatic calibration is build in two parts. The first part find out the zero offset of the capacity measurement. For that the mean value of the capacity measured without connected capacitor is build. A mean value for all 6 measurement combinations is build with 8 repetitions. After successfull determination the zero offsets are written to the EEprom and will be used for further measurements. More difficult was the clearance of the variance of the different ATmega processors for little capacitors ($<40\mu F$), which is shown in Figure 5.33a, 5.33b and 5.34. As a significant reason for this is found the different characteristic (Offset voltage) of the analog comparator.

The date of measurement of nine different processors is shown in figure 5.37 . The "diff2ref" points show the difference of the voltage of a loaded capacitor of $660nF$ to the individual internal reference voltages (band gap). Ideally this difference Voltage should be zero, if the analog comparator has stopped the loading by the signal to the processor. The short handling time of the processor should not result to a measurably rising of the capacitor voltage of this relative big capacitor. The "CapErr" points show the estimated measurement errors of each processor out of figure 5.33a, 5.33b and 5.34 with per mill units. It is noticeable, how the "CapErr" points will follow the "diff2ref" points. Therefore the "diff" points show the difference between the particular "CapErr" and "diff2ref" points. With a mean value of the "diff" points we can get a good estimation for the correction of the capacitor measurements together with the difference voltage of the loaded capacitor and the internal reference.

For the second part of adjustment you must connect a capacitor to pin 1 and pin 3. This capacitor should have a good quality factor and should have a capacity between $100nF$ and $20\mu F$. It should be a film capacitor, as far as possible not a ceramic capacitor und in no case a electrolytic capacitor. You don't need to know the exact value of this capacitor.

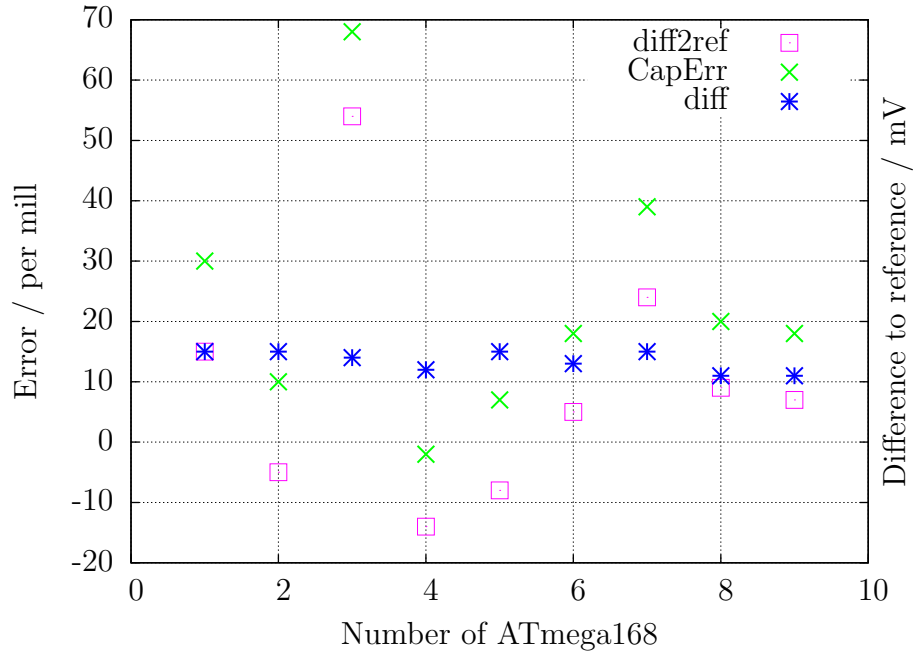
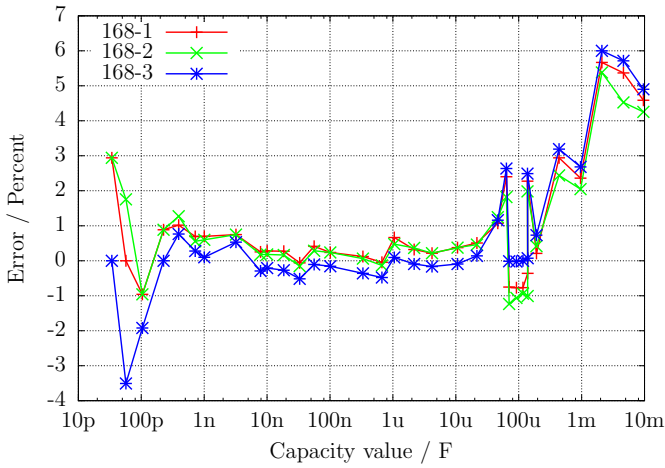
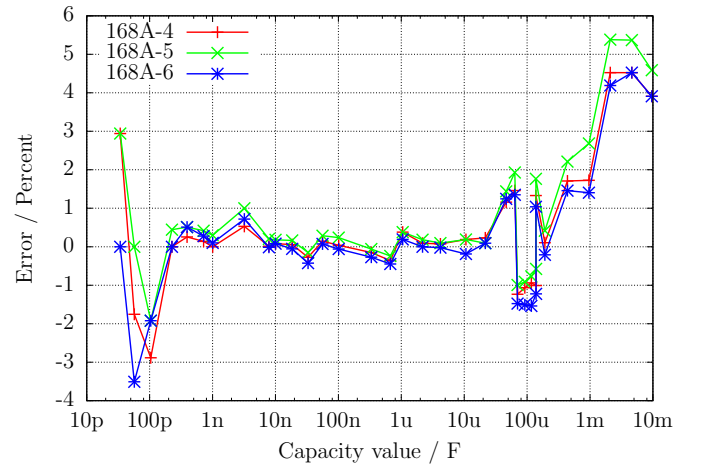


Figure 5.37: Date of nine ATmega168 processors

The figures 5.38a, 5.38b, 5.39, 5.40a and 5.40b shows the measurement results of the different processors with a standard software after the auto calibration. The flash of the processors was loaded with the same software, only for the ATmega168PA the Makefile must be adapted with "PARTNO = m168p". After loading the data the selftest was started for each ATmega and a capacitor with $330nF$ was connected during test No. 10 to pin 1 and pin 3.



(a) three ATmega168



(b) three ATmega168A

Figure 5.38: capacity measurement error, calibrated

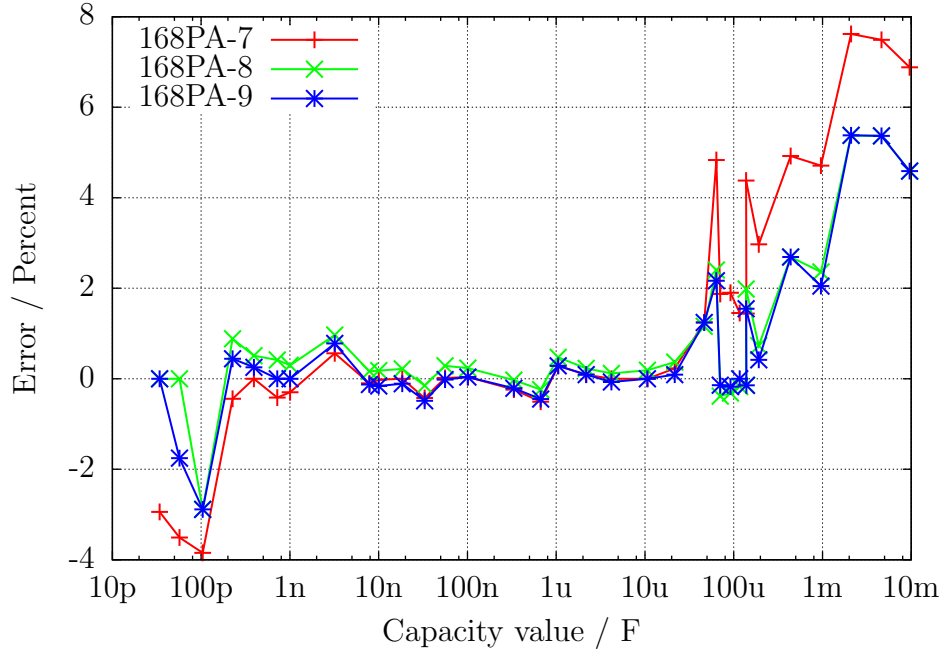
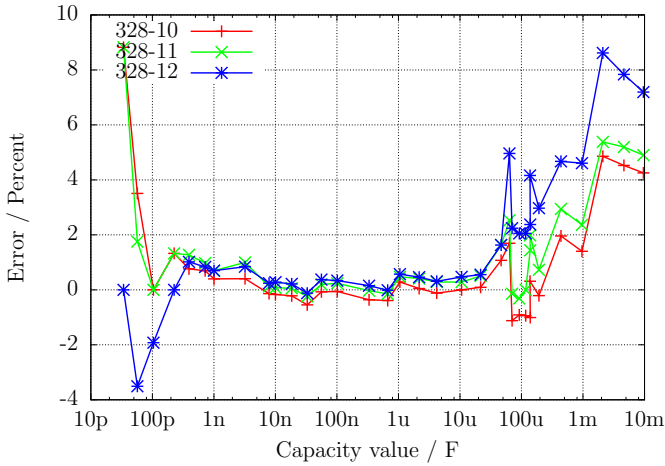
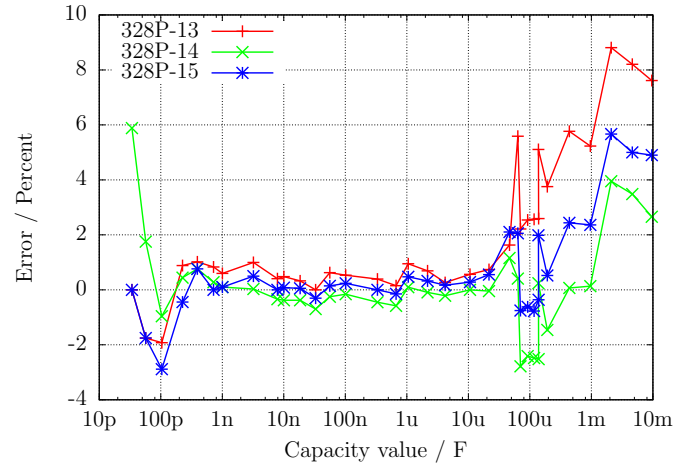


Figure 5.39: capacity measurement error of three ATmega168PA, calibrated



(a) three ATmega328



(b) three ATmega328P

Figure 5.40: capacity measurement error, calibrated

At last I will make more clear the effect of the AUTO_CAL option in the selftest program. The following figure 5.41 shows the results from the three ATmega processors with the biggest error of measurement, one measurement before the calibration and another measurement after the calibration. The points marked with the ending "unc" shows the the errors without calibration. The lines with the ending "cal" shows the error results of the **same processors** with the **same software** after the calibration in the selftest section. The reason for the measurement errors for big capacitors $>(40\mu F)$ is not yet known. All used capacitors for this series of measurements are film capacitors or ceramic capacitors ($56pF$, $100pF$ and $3.3nF$), no electrolytical capacitors are used.

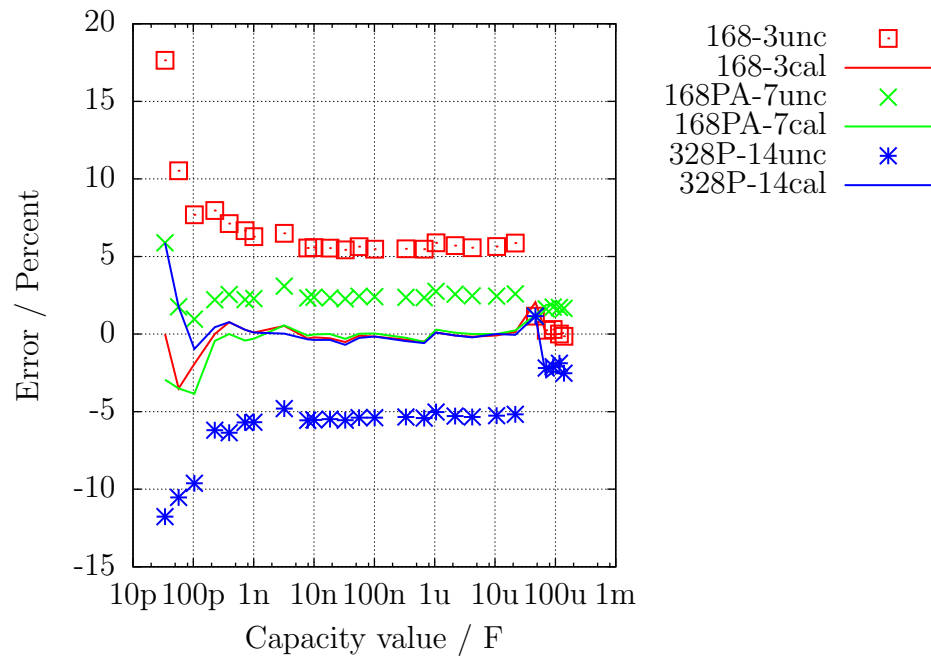


Figure 5.41: Error of capacitor measurement of three ATmega, before and after the calibration

5.4 Measurement of inductance

The measurement of inductance values will be done as separate part with all found resistors with less than 2100 Ω . The method of measurement is based on the growing of current by formula $I(t) = I_{max} \cdot (1 - \exp(-\frac{t}{\tau}))$ after switching on the current. The time constant $\tau = \frac{L}{R}$ is proportional to the inductance L , but reverse proportional to the resistor R . The current can only be measured indirectly with the potential drop of a resistor.

Unfortunately the time constant will be reduced additionally by the relative high resistance 680 Ω , for that the measurement of little inductance values is additionally made difficult with the 8 MHz clock. To get the time constant, the voltage at the 680 Ω resistor will be monitored by the analog comparator. If the voltage drop at the 680 Ω resistor is higher than the voltage of the internal reference, this event will be notified to the 16-bit counter, which is started at the same time of switching current on. The counter will save the state of this event. If the counter will overrun, this will be counted by the program. After the event, the counter will be stopped by the program and the total time will be built with the saved counter stage and the overflow counter. The positive side of the coil will be switched from VCC to GND and hold in this stage until monitoring of the voltages of both pins shows, that no current is detected. The figure 5.42 shown a simplified diagram of the measurement situation.

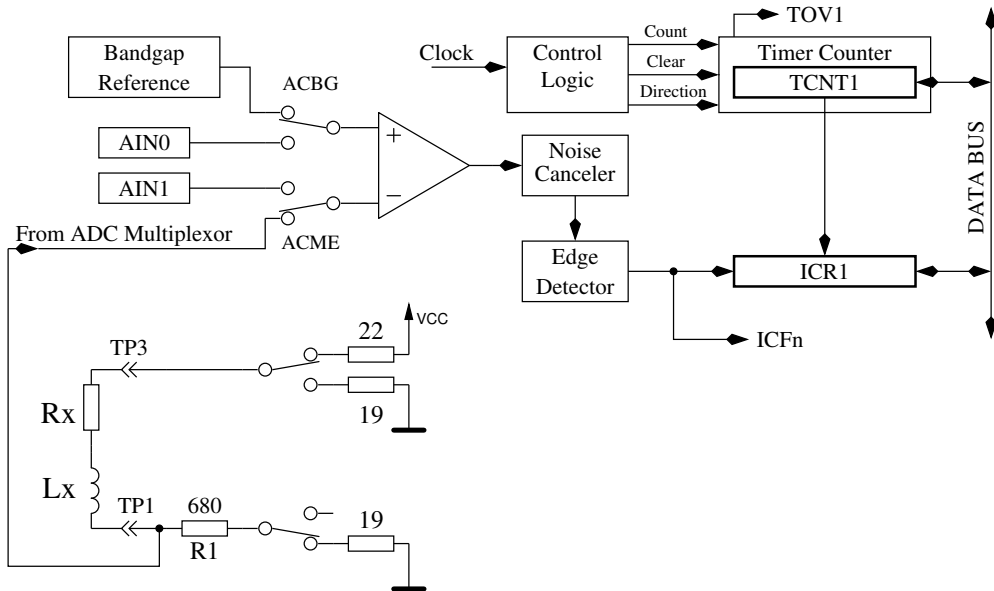


Figure 5.42: Measurement of inductances with the comparator

With the supply voltage VCC and the sum of all resistors in the electric circuit the maximum current I_{max} and from that the percentage of the reference voltage to the maximum voltage at the 680 Ω resistor can be calculated $U_{max} = I_{max} \cdot (680 + 19)$. With the formula $L = -\frac{t \cdot R_{ges}}{\log(1 - \frac{U_{ref}}{U_{max}})}$ the inductance can be calculated. The natural logarithm will be taken out of a build in table.

In order to also measure lower inductance values, the 680 Ω resistor will be omitted in the current loop, if the resistance value of the inductor is measured with less than 24 Ω . Only the output resistance of the port (19 Ω) will be used for measurement of the current. In this special case the peak current will be greater than the value, that the specification of the ATmega allows. Because this will be true only for a very short time, I expect no damage of the ATmega ports. To avoid a longer time with excessive current, the additional measurement with delayed start of the counter will always be done with the 680 Ω resistor. To get better fitting measurement results, a zero offset of 6 is subtract from the counter reading, if the measurement is done without the 680 Ω resistor. Otherwise a zero offset of 8 is subtracted.

With great inductance values the parasitic capacity can cause a quick rise of current, so that the comparator will response immediately. To get the value of the inductance anyway, the measurement will be repeated with a delayed start of the counter. With this methode the voltage grow caused by the current increase of the inductor will be detected by the analog comparator instead of the current peak of the parasitic capacity. The measurements are always done in both current directions. The program will select the higher result of measurement in the same current direction, but the lower result of the different current direction as the displayed result.

5.4.1 Results of the inductance measurements

The figure 5.43 shows the results of the measurement of different inductors. The Inductors above $1H$ are relays or primary sides of power transformers, for which measurements are difficult because the iron core has residual remanence.

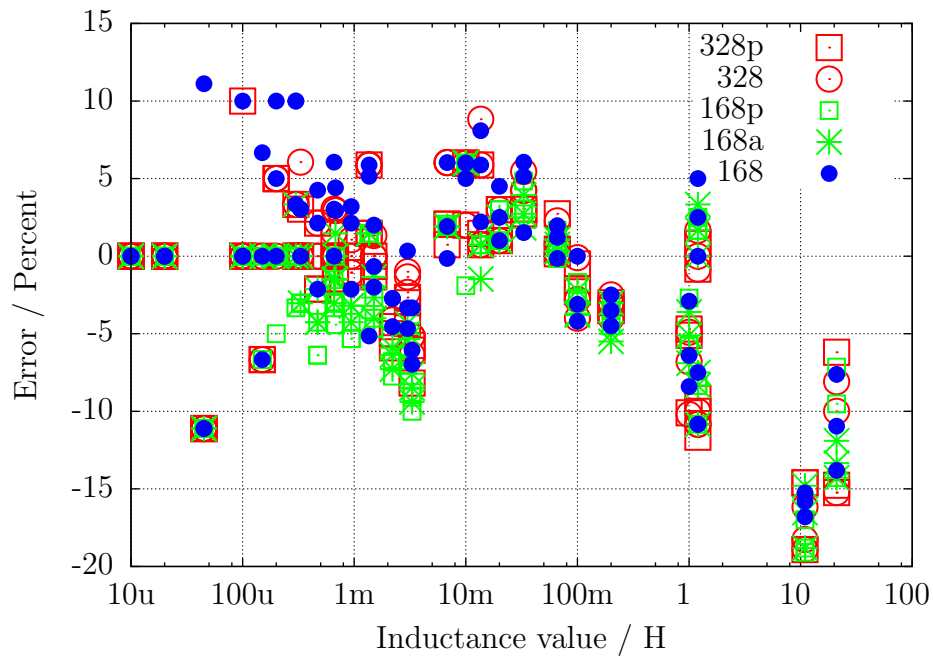


Figure 5.43: Error of inductance measurement of 15 different ATmega

5.5 Selftest Function

Beginning with release 0.9k I have implemented a self test function. Usage is very simple. If you have installed test terminal with clamps, put all clamps together to a piece of uninsulated wire and press the start button. The program notice the shorten probes and start the self test function. After finishing the self test the transistor tester will continue with normal measurement. If no equipment is connected, the program will end with “part unknown or damaged”. You can configure self test only for a ATmega168 or ATmega328. The separate steps of the self test function 1 to 6 is displayed on row 1 of the LCD display with the letter T followed by the step number. Every step is repeated 4 times, before the program continues with the next step. But if you hold the start key pressed, when the test cycle is finished, this test is not repeated any more. If you leave the key pressed the total time, every test is executed only once.

Without the AUTO_CAL option only measurement results are displayed in every step, no error analysis are done, you must interpret the results yourself. At this place I will give you an additional important hint. Never do a measurement with connected ISP plug! The ISP interface influences the measurement. Here is the list of currently implemented tests:

- Measurement of the 1.3V (or 1.1V) reference Voltage (band gap Reference).** In row 1 the text “Ref=” and the measured Voltage in mV is displayed. For the ATmega8 the voltage should be near to 1.3V. For the other processors the voltage should be near to 1.1V. The second row shows the resulting factor for the capacity measurement with the 470kΩ resistor.
- Comparing of the 680Ω resistors.** In row 1 the cryptic text “+RL- 12 13 23” is shown. Meaning of this is as follows: The RL is the short form of Resistor Low meaning the 680Ω resistors. The 12 stand for: resistor at pin 1 is connected to VCC (+) and resistor at pin 2 is connected to GND (-). The result of this measurement is displayed in row 2 at the first place as difference to the theoretical value. In row 1 follows now a “13” which means, that the first connection of measurement 1 is still connected with 680Ω to VCC but that the resistor of pin 3 is connected to GND. The result is displayed in the middle place of row 2 as difference to the theoretical value. The last measurement of this test “23.” means that now the resistor at pin 2 is connected to VCC (+) and the resistor of pin 3 is connected to GND. The result of measurement is displayed at the last place of LCR row 2 as difference to the theoretical value. Please remember, that the resolution of the ADC is about 4.88mV! The measurement situation is also shown in figure 5.44. The theoretical value with respect to the internal resistance of the pins should be: $\frac{5001 \cdot (19+680)}{(19+680+680+22)} = 2493$.

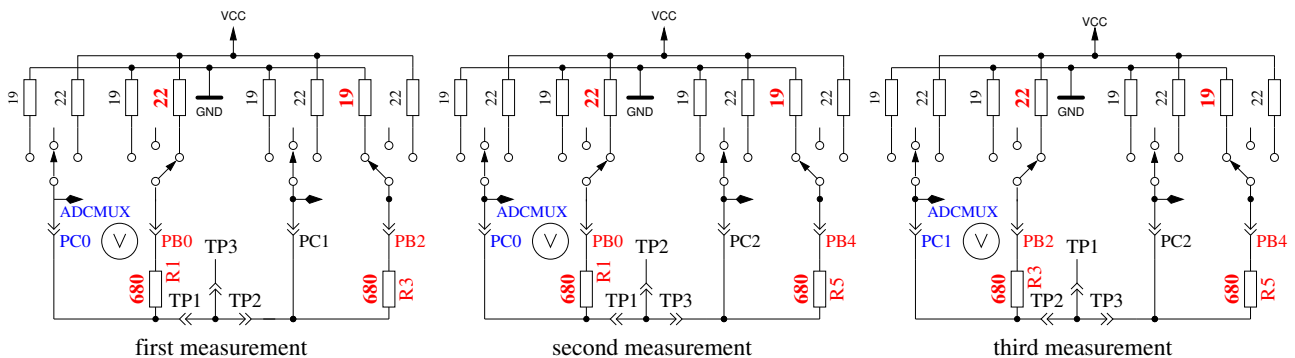


Figure 5.44: Comparison of 680Ω resistors

3. **Comparing of the 470kΩ resistors.** Now the display shows in row 1 “+RH- 12 13 23”. The same procedure as done in step 2 is repeated with the 470kΩ resistors (symbols RH). All results are shown as difference to the theoretical value. The theoretical value is this time $\frac{5001 \cdot (19+470000)}{(19+470000+470000+22)} = 2500$ for all combinations.
4. In this step nothing is measured, but the **order is displayed isolate Probe!**, which means that it is time to separate the probes (release from wire).
5. **This step tests the capability of GND (-) connected 470kΩ resistors (H) to pull the test pins to GND.** Row 1 shows the text “RH-”. Row 2 should display zero for all three pins.
6. **This step tests the capability of VCC (+) connected 470kΩ resistors (H) to pull the test pins to VCC (+).** Row 1 shows the text “RH+”. The results are shown als difference to VCC and should be near zero. Great differences from the best value for test 5 and 6 are errors such as isolation problem, flux material or damaged port.
7. **Measuring of internal resistance of pin output switched to the GND signal.** This test and the follwing tests will only be done, if the option AUTO_CAL is selected. The internal resistance of the port C outputs switched to GND (-) are measured with the current of to VCC (+) switched 680Ω resistors, see Figure 5.45. Only the three pins of the ADC port are measured, the resistor port B (PB0,PB2 and PB4) can not be measured without hardware modification. Is is assumed that the port resistance of the different ports are nearly identical. The resistor value will be shown in the next test.

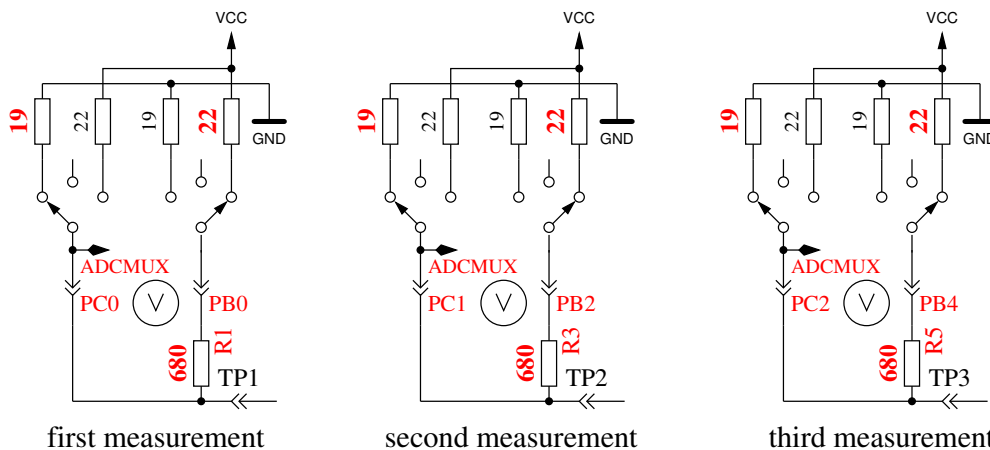


Figure 5.45: Measurement of internal resistance of Port C switched to GND

8. **Measuring of internal resistance of port outputs switched to the VCC (+)signal.** The needed current is generated with to GND connected 680Ω resistors . It are the same measurements as those in test 7 to the other side as you can see in Figure 5.46. With the following steps the resistance is computed: To get the current, the following is computed: $(VCC - (resultoftest7) - (resultoftest8))/680$. To get both resistor values, the voltage (result of test 7 or 8) is divided by this current. The result for this test will then be notified in row 1 with the text "RI.Hi=", the resistance value (Ω) to the GND side is displayed in row 2 with the text "RI.Lo=". Both results will be written to the EEprom memory and will be used for further measurement.

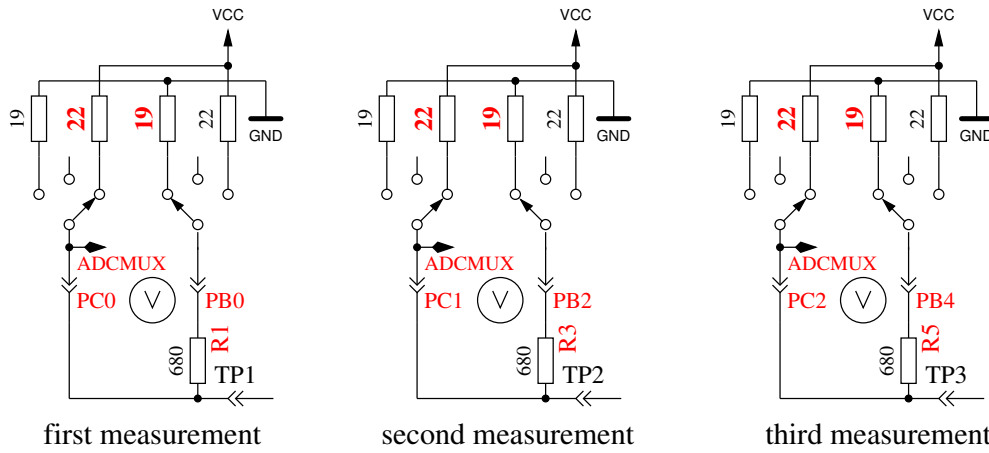


Figure 5.46: Measurement of internal resistance of Port C switched to VCC

9. **Measurement of the zero offset of the capacitor measurement.** The zero offset for the capacity measurement with pin combinations 1:3, 2:3 and 1:2 is shown in that order in display row 1 following the “C0”. All three values are shown in pF units. For this measurements no predefined zero offset is respected. The zero offsets of pin combinations in opposite order is also measured. The results will be written to the EEprom, if all values are less than $70pF$. This will be notified by the output of “OK” in row 2. The found zero offsets are used for further capacity measurements with respect to the pin combination. Please notice, that changes of the test equipment can cause a new adjustment of the zero offset. If you use wire with clips, the zero offset may be 3 pF greater compared to a empty socket.
10. **Wait for the connection of a capacitor to pin 1 and pin 3.** The message “1-C-3 >100nF” is shown in row 1 of LCD. To prepare the measurement of the comparator offset voltage, you must connect a sufficient big capacitor to pin 1 and pin 3. It should be a capacitor with a high quality factor and a capacity between $100nF$ and $20\mu F$. You should never use electrolytical capacitors, use film capacitors instead.
11. **Measurement of the comparator offset for capacitor measurement adjustment.** To get the offset of the analog comparator, a capacitor must already be connected to pin 1 and pin 3. The capacitor is needed for buffering the load voltage of a capacitor, in order to get the voltage difference of load voltage to the internal reference voltage (band gap). If measurement is successfull, the correction value is short shown with the text “REF_C=” in row 1 of the LCD and written to the EEprom. You can give a additional offset to the automatic measured value with the REF_C_KORR option.

If you have selected the AUTOSCALE_ADC option, the gain of the ADC readings with the internal reference will be adjusted by comparing a capacitor voltage below 1 V once readed with VCC reference and once readed with the internal reference. The measurement result is shown in row 2 with the text “REF_R=”. Your REF_R_KORR value is a additional offset to this automatic find out difference value.

At the end of test function the text “Test End” is shown in row 1 and the version number of software is shown in row 2. If the Makefile option FREQUENCY_50HZ is set, a **50Hz rectangle signal** is generated on pin 2 and the same signal in opposite direction on pin 3. Pin 1 is switched to GND. The current is limited with 680Ω resistors. This will be notified by the Output of “50Hz” at the end of row 1 of the LCD display. The 50Hz signal will be generated 30 times for 2 seconds each. You can check the time of the wait calls, if you have an oscilloscope or frequency counter. If you don’t use the crystal clock version, the result may be inexactly. A exactly clock frequency and

wait time are important for measurement of capacity values. You can abort the generation of the 50Hz signal by long time pressing of the start button. Then the program continues with the normal measurement task.

5.5.1 Some Results of the Selftest Function

The results of the selftests of nine different ATmega168 processors and of six ATmega328 processors will be shown in the following figures.

Test No.	measurement typ	theoretical	figure
Test 1	band gap Ref	1100	5.47
Test 2	RL-Mean	0	5.48a
Test 3	RH-Mean	0	5.48b
Test 5	RH-Low	0	5.49a
Test 6	RH-High	0	5.49b
Test 7	R out Lo	131	5.50a
Test 8	R out Hi	151	5.50b
Test 9	Cap zero offset	30	5.51
Test 11	Reference correction	0	5.52

Table 5.5: Table of the selftest figures

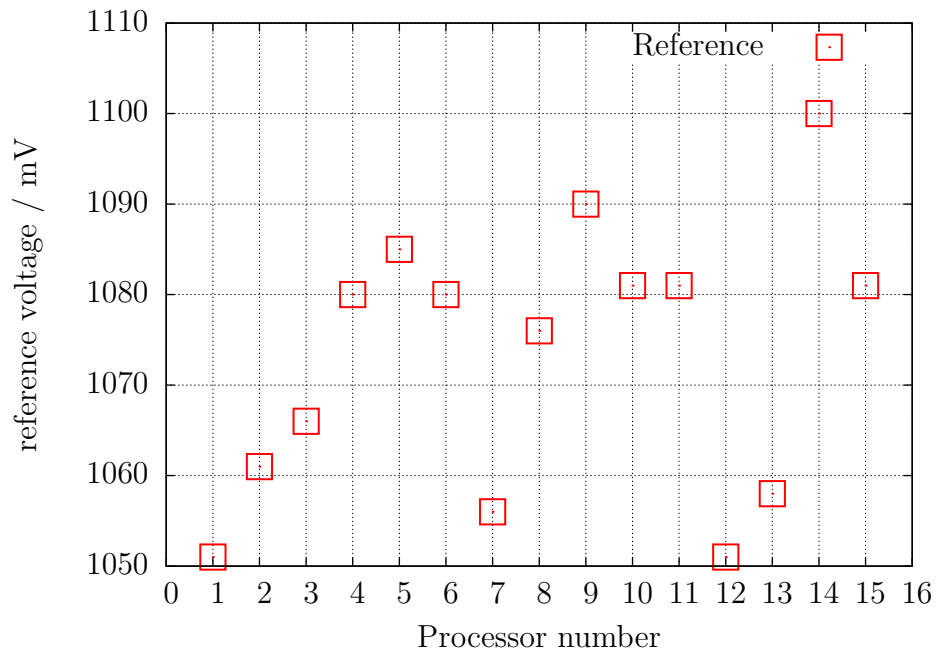
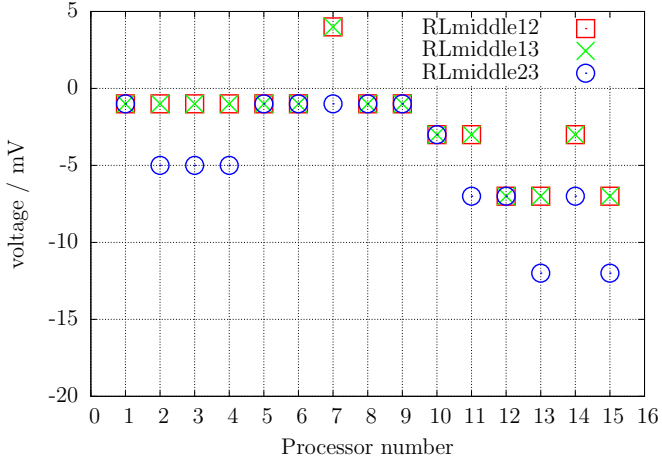
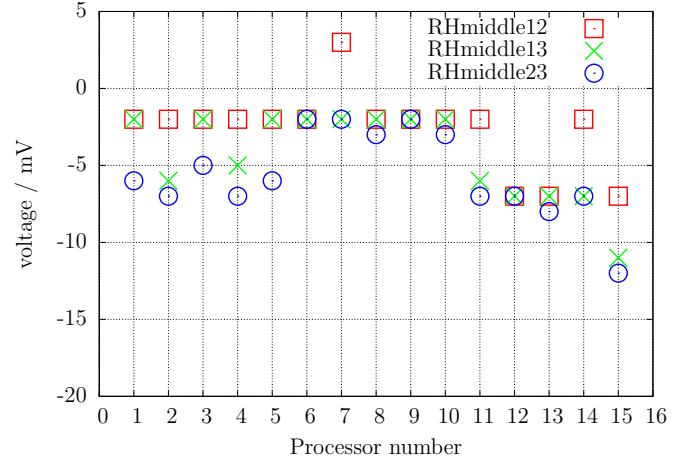


Figure 5.47: Selftest: Reference-Voltages

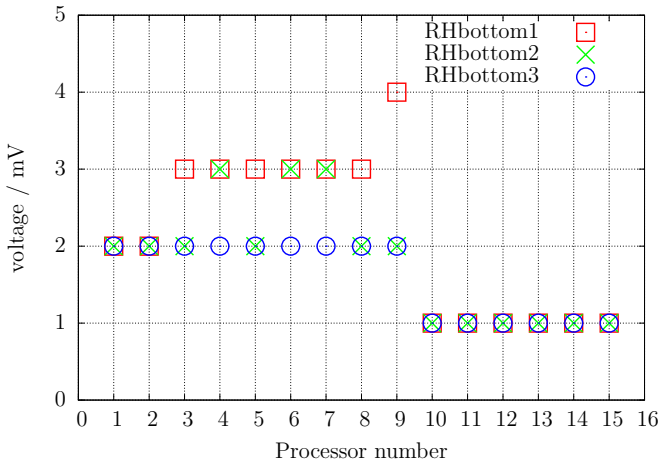


(a) with 680Ω

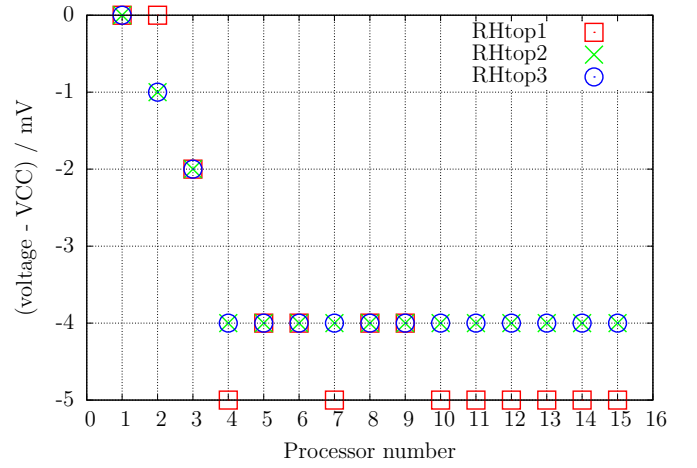


(b) with $470k\Omega$

Figure 5.48: Selftest: difference to ideal mean voltage

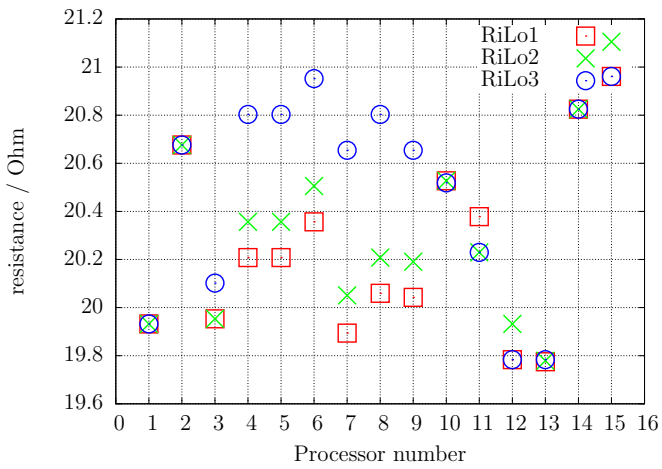


(a) with $470k\Omega$ to 0V

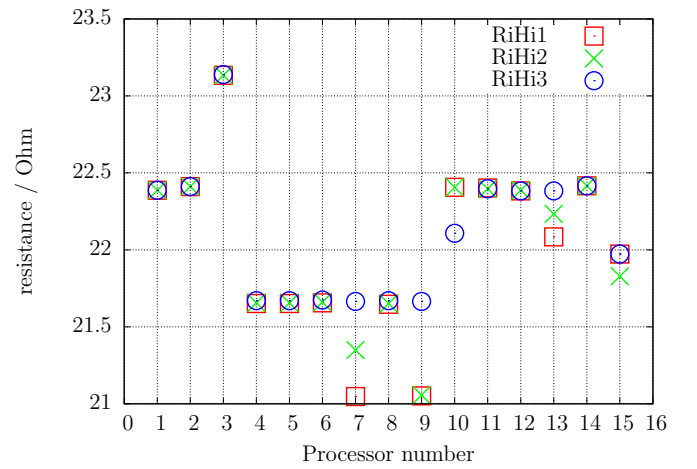


(b) with $470k\Omega$ to 5V

Figure 5.49: Selftest: Input voltage



(a) with 680Ω to 5V



(b) with 680Ω to 0V

Figure 5.50: Selftest: Output resistance

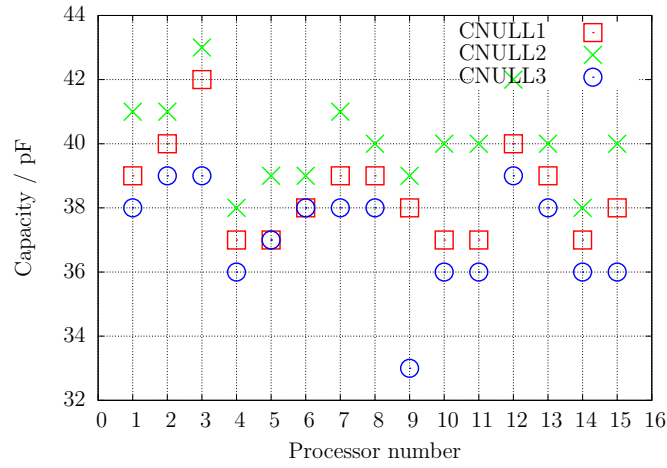


Figure 5.51: Selftest: zero offset of the capacity measurement

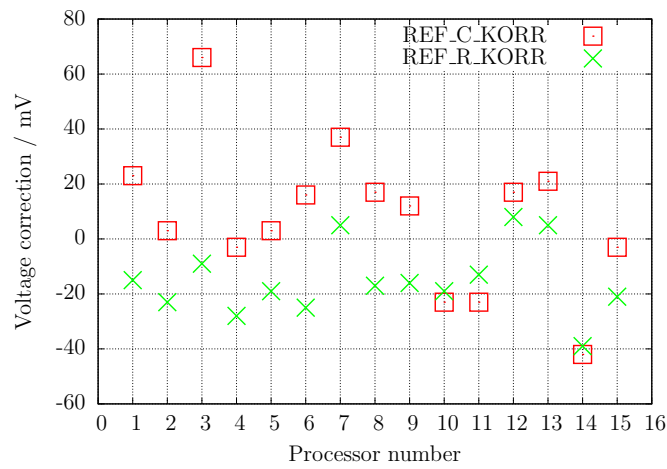


Figure 5.52: Selftest: correction values after automatic calibration

At last I would like to show you the difference voltages of the external at the AREF pin with a multimeter measured voltages and the internal with the ADC measured voltages of the reference voltages of 15 different ATmega precessors and the found correction voltages (REF_R_KORR) after the automatic calibration in figure 5.53. You can see, that the automatic calibration values nearly follow the external measured values.

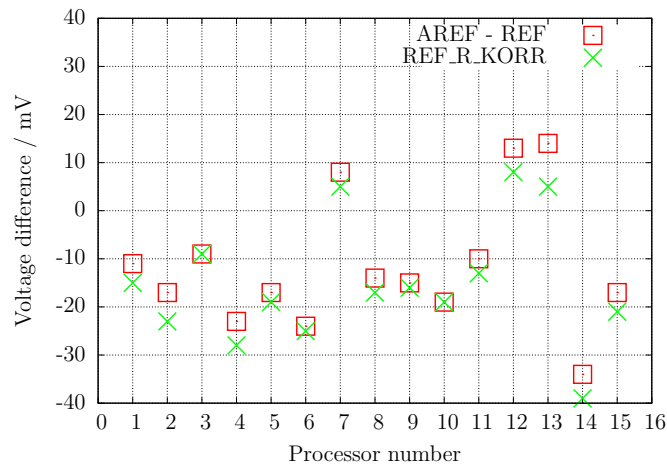


Figure 5.53: Selftest: Voltage difference of the internal reference

Chapter 6

Known errors and unsolved problems

Software Version 1.04k

1. Germanium Diodes (AC128) are not detected in all cases.
2. Capacity value in reverse direction for Power Schottky Diodes such as MBR3045PT can not be measured, if only one diode is connected. The reason is a too big residual current of this diode. Sometimes the measurement is possible by cooling down the device (with cooling spray for example).
3. Here and there a wrong detection of the 2.5V precision referenz is reported, when the PC4 pin (27) is unconnected. You can avoid this behaviour with a additional pull up resistor connected to VCC.
4. The diode function of a triac gate can not be examined.
5. Sometimes a problem with the Brown Out level of 4.3V is reported for ATmega168 or ATmega328 processors. This will cause a reset during capacity measurement. A reason is not known. The Resets will disappear, if the Brown Out level is set to 2.7V.

Chapter 7

Special Software Parts

Several modifications are done to save flash memory. The LCD-Output of probe-pin numbers was done in the form `"lcd_data('1'+pin)"`. To save the add operation for every call, the entry `"lcd_testpin(uint8_t pin)"` was added to the `lcd_routines.c`.

The pseudo calls in the form `"_delay_ms(200)"` are not implemented as library calls, but wait loops are implemented for every call. This will consume much memory, if you have many calls at different location in your program. All of this pseudo calls are replaced with calls to my special assembly written library, which uses only 74 bytes of flash memory (@8MHz), but enables calls from `wait1us()` to `wait5s()` in steps of 1,2,3,4,5,10,20... The routines include the Watch Dog Reset for all calls above 50ms. Every wait call usually only need one instruction (2 Byte). Wait calls with interim value such as 8ms need two calls (5ms and 3ms or two times a 4ms call). I don't know any implementation, which is more economical if you use many wait calls in your program. The calls uses no registers, only the Stack Pointers for the return addresses in the RAM (at most 28 Byte stack space in current release) is used. The total list of functions is:

`wait1us()`, `wait2us()`, `wait3us()`, `wait4us()`, `wait5us()`, `wait10us()`,
`wait20us()`, `wait30us()`, `wait30us()`, `wait40us()`, `wait50us()`, `wait100us()`,
`wait200us()`, `wait300us()`, `wait400us()`, `wait500us()`, `wait1ms()`,
`wait2ms()`, `wait3ms()`, `wait4ms()`, `wait5ms()`, `wait10ms()`,
`wait20ms()`, `wait30ms()`, `wait40ms()`, `wait50ms()`, `wait100ms()`,
`wait200ms()`, `wait300ms()`, `wait400ms`, `wait500ms()`, `wait1s()`,
`wait2s()`, `wait3s()`, `wait4s()` and `wait5s()`;

That are 36 functions with only 37 instructions inclusive Watch Dog Reset! There is really no way to shorten this library. Last not least matches the wait calls the exactly delay time, if the lowest wait call does. Only the wait calls above 50ms are one cycle per 100ms to long because of the additionally integrated watch dog reset.

Additionally the often used calling sequence `"wait5ms(); ReadADC...();"` is replaced by the call `"W5msReadADC(...);"`. The same is done for the sequence `"wait20ms(); ReadADC(...);"` which is replaced by one `"W20msReadADC(...);"` call. The function `ReadADC` is additionally written in assembly language, so that this add-on could be implemented very effective. The functional identical C-version of the `ReadADC` function is also available as source.

Chapter 8

To Do List and new ideas

1. Add more and better documentation.
2. Check if transistor tester could get better interpolated ADC values if additional noise is added to the signal or to the ADC reference (see ATMEL document AVR121: Enhancing ADC resolution by oversampling). If all items are identical, there can't be any enhancement of resolution by oversampling. Can enough noise be generated with the ATmega counter? How additional noise affects the upper and lower limit values? Of course this method can not eliminate all of the ADC errors.
3. This method can be tested by building a ramp input signal and monitoring this signal. The ramp signal can be build by slowly charging a big capacitor with the 470k resistor. The growing of the voltage can then be monitored with the LCD display in a special part of self test.
4. Think about how we can get the real internal resistance of port B output (resistor switching port) instead of assuming, that ports are equal.
5. Can discharging of capacitors be made more quickly, if the minus pin is additionally raised with the 680 Ω resistor to VCC (+)?
6. Check if the tester can use floating-point representation of values. The risk of overflow is lower. There is no need to use multiplication and division together to build a multiplication with a non integer factor. But I don't know how much flash memory must be spend for the library.
7. Write User's guide for configuring the tester with the Makefile options and description of the build chain.
8. If the holding current of a thyristor can not be reached with the 680 Ω resistor, is it harmless to switch the cathode directly to GND and the anode directly to VCC for a very short time? The current could reach more than 100mA. Will the port be damaged? What is with the power supply (voltage regulator)?
9. Check the Port afterwards with self test function!
10. Can voltage regulators be checked? (Input, Output, GND)
11. Can optoelectronic couplers be checked?
12. Warning message, if the found reference voltage is not plausible in relation to ATmega model and VCC.

13. What is about a second generation tester with a bigger ATmega which includes differential ADC-port, more flash memory . ? There is no ATxmega which have supply voltage of 5V, only the ATmega line is possible.
14. Idea for a New Projekt: USB version without LCD-Display, Power from USB, Communication to PC over a USB-Serial bridge.

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